PREPARATION AND CHARACTERIZATION OF FORSTERITE AND MEASUREMENT OF ITS DIELECTRIC CONSTANT AND LOSS FACTOR IN THE FREQUENCY RANGE OF 50 Kc/s—25 Mc/s

A Thesis Submitted
in Partial Fulfilment of the Requirements
for the Degree of
MASTER OF TECHNOLOGY

By PRABHAT KUMAR GHOSH

to the DEPARTMENT OF METALLURGICAL ENGINEERING

INDIAN INSTITUTE OF TECHNOLOGY, KANPUR

JANUARY, 1979

CENTRAL HARARY

ACE No. A 58752

3 JUL 1979

ME-1979-M-GHO-PRE

#### CERTIFICATE

Certified that the thesis entitled 'Preparation and Characterization of Forsterite and Measurement of its Dielectric Constant and Loss Factor in the Frequency Range of 50 Kc/s - 25 Mc/s' has been carried out under my supervision and has not been submitted elsewhere for a degree.

(A. R. Das)
Professor
Department of Metallurgical Engineering
Indian Institute of Technology,
Kanpur

#### ACKNOVLEDGEMENTS

With a profound sense of gratitude, I wish to acknowledge Professor A. R. Das under whom this work has come to a successful completion. His lively interest, inspiring guidance, illuminating suggestions and optimistic as well as open minued approach to problems have brought forth this dissertation in the present form.

I owe much to Professor E. C. Subbarao for his interest in this study as well as for his generous permission in allowing me to use his instruments. I am also grateful to Professor D. Chakravorty and Professor D. K. Paul for their active interest in this endeavour.

I acknowledge Mr. B. Sharma, Mr. R. K. Prasad, Mr. Malaviya, Mr. A. K. Singh and Mr. Basak for the assistances rendered by them in the different phases of work. I am grateful to Mr. P. K. Nandi for his immense help.

I am highly indebted to my friends Messrs G. C. Das,

A. Sen, H. P. Kaza, P. Sarkar, R. N. Chatterjee, P. Mukherjee,

S. Ganguly, S. Dutta, S. N. Paul, N. K. Ghosh and Partha

Sarkar who have provided me with their entertaining company

during the pastime I had. I shower a lot of hearty thanks

on them.

I am thankful to h.r. Bhamra for materialisation of the different schemes into actual experimental apparatus,
Mr. V. P. Gupta for accurate tracing of the figures, Mr. Nihal Ahmaa for excellent typing the winged manuscript and

Mr. Viswanath for neat ammonia printing and cyclostyling.

I owe a special debt to my parents for their kind understanding and perseverence for this period when I had to keep myself away from them.

Prabhat Kumar Ghosh

## CONTENTS

			Page
LIST OF	PABLES		vii
LIST OF 1	FIGURES		xi
ABSTRACT			xiii
CHAPTER I	L INTRO	LUCTION	1
CHAPTER 2	2 EXPER	IMENTAL PROCEDURE	12
	2.1	Raw Materials	12
	2.2	Material Preparation	12
	2.2.1	Weighing	12
	2.2.2	Mixing and Grinding	13
	2.2.3	Calcination and Forsterization	14
	2.3	X-ray Powder Diffraction	14
	2.4	Sample Preparation	14
	2.5	Sintering	15
	2.6	Polishing	17
	2.7	Sample Density	17
	2.8	Water Absorption	18
	2.9	Electroding and Wiring	18
	2.10	Measuring Methods and Elimination errors	of 19
CHAPTER	3 RESUL	TS AND DISCUSSION	26
	3.1	Processing	26
	3.1.1	Raw Materials	26
	5.1.2	Mixing and Grinding	26
	5.1.3	Calcination and Forsterization	26
	3.1.4	Sample Preparation	27
	3.1.5	Sintering	28
	3.2	A-ray Analysis	29
	3.3	Errors in Electrical Measurements	35
	3.3.1	Electroded and Wired Sample	35

		vi
	3.3.2 Variation of Number of Leads and Lead Length	35
	3.5.3 Electroded Samples between Parallel Plates	37
	3.3.4 Measurement with Capacitance Cell	38
	3.4 Data on K and Q Measurements	45
CHAPTER 4	COMCLUSION	49
CHAPTER 5	SUGGESTIONS FOR FURTHER WORK	50
TABLES		51
FIGURES		98
REFERENCES		110
APPENDIZ I		113
APPENDIK I		116

# LIST OF TABLES

Table	Mo.	Page
.1	Jan-I-10 Minimum Requirements for Insulating	
	Ceramics, Radio Class L	51
2	Typical Properties of Steatite and Forsterite	52
3	Forsterite Composition Laturing Around 1250°C (Cons 10)	53
4	Dielectric Properties at High Frequencies (After Hef. 6, Table 3)	54
5	Dielectric Properties of Samples of Stoichio- metric Forsterite Plus Additions of Different	
	Percentage of Korean Kaolin; FK-0 (F 100 K 0), FK-1 (F 97.5 K 2.5), FK-2 (F 95 K 5), FK-3	
	(F 92.5 K 7.5) and FK-4 (F 90 K 10). (After Ref. 10, Table 6)	55
6	Composition of Various Batches of Forsterite	56
7	Analysis of MgCC3, SiO2, Talc, Magnesite and Ball Clay	56
8	Progressive Lensification Lata for Lifferent Foresterite Batches of Stoichiometric Talc-Magnesite Composition	57
		71
9,4	Densification and Thermal History of the	
	Forsterite Samples Used for Electrical Measure- ments	- 58
10	Densification Lata and Thermal History of Forsterite Samples of Stoichiometric Talc-	
	Magnosite Composition Used for A-ray Diffrac-	59
11	Thermal History and Composition of Forsterite	
	Samples Used for X-ray Liffraction	60

I'a	ble No	Pa	age
	21	K-ray Diffraction of Stoichiometric Forsterite Composition with Mg(OH) <sub>2</sub> and SiO <sub>2</sub> both Sintered at 1200°C for 12 hours	72
	22	X-ray Diffraction of Stoichiometric Forsterite Composition of Talc, Magnesite with Additives, both Sintered at $1100^{\circ}$ C for $4\frac{1}{2}$ hours	73
	23	K-way Diffraction of Stoichiometric Porsterite Composition of Tale, Magnesite with Additives, both Sintered at $1100^{\circ}$ C for $4\frac{1}{2}$ hours	74
	24	X-ray Diffraction of Stoichiometric Forsterite Composition of Talc, Magnesite with Additives, both Lintered at 1200°C for 5 hours	75
	25	N-ray Liffraction of Smoichiometric Forsterite Composition of Talc, Magnesite with Additives, both Sintered at 1200°C for 5 hours	76
	26	Unidentified X-ray Liffraction Lines in Forsterite Compositions	77
	27	Measurement of K and Q of Electroded Forsterite Samples Using Iwo Connecting Leads on Each Face	78
	28	Measurement of L and Q of Unshielded and Elec- trodes Morsterite Sample Using Different Number of Leads and Different Lead Length	79
	29	Measurement of K and G of Unshielded and Elec- troded Forsterite Sample Using Different Lead Lengths	80
	30	Measurement of K and Q of Unguarded, Electroded and Wired Forsterite Sample	81
	31	Measurement of K and Q of Forsterite Samples, Sintered at 1150°C and 1200°C for 5 hours,	82
		14.15457. 12.1 1.1 X3.1 X3.1 X3.1 V 1.16.1 N 1.1124 1.11.1(1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.1.	~ ~ /

labl	e N	o.	`age
3	2	Measurement of H and Q of Electroded Forsterite Samples Using Parallel Plate Set up	84
3	<u>م</u>	Measurement of H and Q of Electroded Forsterite Samples Using Parallel Flate Setup With Sharp and Flat Contacts at Either Ends	84
3	4	Measurement of K and $\zeta$ of Air by the Unguarded Capacitance Cell	85
5	5	Measurement of $\Delta$ C and Q of Unguarded Foresterite Samples Using Capacitance Cell	86
3	6	Measurement of $\triangle$ C and Q of Unguarded Foresterite Sample with Varying Electrode Baking Time Using Capacitance Cell	87
3	7	Measurement of K and Q of Air Using Capacitance Cell	88
3	8	Measurement of $\triangle$ C and Q of Air Using Capacitance Cell	90
3	9	Measurement of $\triangle$ C and Q of Air Using Capacitance Cell	91
4	0	Measurement of K and Q of Unelectroded and Unguarded Sample (XVII) Along with Air Using Capacitance Cell.	92
4	1	Measurement of K and Q of Forsterite Samples,	
		Fired at 1200 °C for 5 hours, in Capacitance Cell made of Aluminium	94
4	2	Variation of the K value with Change in Density	95
4	3	Measurement of R and Q of Electroded and Wired Forsterite Samples	96
4	4	Measurement of E of Electroded and Wired Forstorite Samples with Varying Thickness	97

# LIST OF FIGURES

Figur		Page
1	Schemes of Polymorphism of MgSiO <sub>3</sub> (after Ref.5)	98
2	Intensity of Diffraction Patterns at Various remperatures of Calcination (after Ref. 6, Fig.1)	99
3	Intensity Changes of Diffraction Pattern of Composition 95 / (2MgC) (1.2 SiC <sub>2</sub> ) with 5 / Maolin (PSF-O) (after Ref. 6, Fig. 3).	100
4	Intensity Changes of Liffraction Pattern of Composition 85 / (2MgO)(1.2 SiO <sub>2</sub> ) with 5 / Kaolin and 10 / EaCO <sub>3</sub> (PSF-B) (after Ref.6, Fig. 4)	101
5	Formation of Forsterite from Different Particle Size Materials of MgU, SiO <sub>2</sub> , MgO·SiO <sub>2</sub> (after Ref. 7, Figs. 4, 5, and 6)	102
6	Sketch of Electroded and Wired Forsterite Samples	103
7	Circuit for Measuring the Dielectric Constant and Q-Factor of the Sintered Disc Samples by Parallel Connection	104
8	Sketch of Parallel Plate Setup for Measuring K, the Dielectric Constant and Q, the Quality Factor of Sintered Forsterite Samples	105
9	Sketch of Unguarded and Unshielded Capacitance Cell for Measuring R, the Lieloctric Constant and Q, the quality Factor for Sintered Disc Samples	106
10	Sketch of Guarded and Shielded Capacitance Cell for Measuring L, the Lielectric Constant and Q, the Quality Factor for Sintered Lisc Samples	107

		xii
Figure		Page
11	C versus A/t Plot for Finding out actual K	
•	value of Air	108
12	Variation of Relative biclectric Constant K	
	with Sample Thickness for Forsterite Material	
	with Talc-Magnesite and BaCO3 Additive	109

#### ABSTRACT

Forsterite samples were prepared from pure MgO-SiO2 and talc-magnesite. In the talc-magnesite batches, ball clay and BaCO2 were also used as additives. Samples of 2" diameter were prepared and sintered at different temperatures ( $1125^{\circ}$ C-1400°C) for different times ( $4\frac{1}{2}$  hrs.-20 hrs.). X-ray analysis was performed for identification of phases. Sintered samples were polished and the measurement of the relative dielectric constant K and the quality factor Q were conducted in the frequency range of 50 Kc/s-25 Mc/s using a Boonton Radio Co. Q-meter Model 260-AP. Both the electroaed and unelectroded samples were used in wired and unwired condition. Capacitance cells, which had been used to eliminate extraneous effects were not found helpful and were discarded. Finally the K and Q measurements were done with electroded and wired forsterite samples. For the best sample, made of talc-magnesite and 6.54 percent BaCO3, having a relative density of 0.93, the K and tano values were 6.63 and 5x10-4 respectively and that of pure Mg0-Si0, with relative density 0.89 had shown K = 5.55 and  $tan\delta = 14x10^{-4}$ Higher density samples had shown higher K and Q values.

#### CHAPTER 1

#### INTRODUCTION

For application as high frequency insulation ceramic products are required which are dimensionally stable, have good mechanical strength, and have a low loss factor. Requirements and classification for these materials are indicated in Table 1. Low loss steatite is the most widely used material as it is surpassed for economy in manufacture, because the talc used in the composition is easily pressed and causes the least die wear. The resulting product consists of mainly clinoenstatite in a glassy matrix. Steatite bodies usually come in class L-3 to L-5 of Table 1.

For lower dielectric losses, forsterite ceramics having Mg<sub>2</sub>SiO<sub>4</sub> as a main crystalline phase are frequently used. Alkaline earth oxide fluxes are used to give excellent dielectric properties. The high expansion coefficient is detrimental for thermal shock but it is an advantage for forming ceramic-metal seals, since it provides good match for some of the nickel-iron alloys. Table 2 gives typical property descriptions of steatite and forsterite ceramics.

Forsterite has an orthorhombic crystal structure  $^{25,26}$  with a = 4.76 Å, b = 10.21 Å, c = 5.98 Å and c' = 5.96 Å. It is such that each silicon atom is surrounced by a tetrahedral group of four oxygen atoms and each magnesium is surrounced octahedrally by six oxygen atoms.

In the  ${\rm Mg0-Si0}_2$  system, the two stable phases are forsterite ( ${\rm Mg}_2{\rm Si0}_4$ ) and enstatite ( ${\rm Mg}_3{\rm Si0}_3$ ), besides periclase ( ${\rm Mg0}$ ) and silica. The melting point of forsterite is  $1890^{\rm O}$ C. Forsterite ceramics have been in commercial use in the USA, Europe and Japan.

Navais in a detailed report on a large number of electrical insulators, states that steatite has been the accepted generic name for high-talc containing bodies which in firing develop the mineral clinoenstatite (MgO·SiO<sub>2</sub>) and some cristobalite. These insulators have been used in large quantities for many radiotransmitter parts during World War II and had good dielectric properties and low Power Factor (~0.002) in 300 kc-lmc range with some going as low as 0.0004. Unfortunately they became quite lossy at centimeter and lower wavelengths. In contrast, forsterite composition such as shown in Table 3 maturing at 1250°C shows remarkably low losses.

Atlas<sup>2</sup> in his paper reviewed the earlier works on phases of MgSiO<sub>3</sub> and mentions the conclusion of the earlier workers Allen, Wright and Clement (1906) that four crystalline modifications, i.e. rhombic enstatite, monoclinic clinoenstatite and two more phases of orthorhombic and monoclinic amphiboles exist. Of these, the only stable phase at all temperatures was enstatite and that the other phases formed metastably below 1100°C. Atlas in his

investigations, however, showed the existence of two stable phases, i.e. rhombic enstatite occurring upto 985°C and protoenstatite occurring above 985°C upto the point of dissociation into forsterite and liquid. Clinoenstatite was considered to be a low temperature metastable phase formed from protoenstatite by rapid cooling. The transition rhombic enstatite protoenstatite was reconstructive and was accelerated by a flux whereas transformation of protoenstatite to clinoenstatite was displacive.

Thurnauer<sup>3</sup> had discussed forsterite as a low loss material. Zaikina<sup>4</sup> discussed the formation of clinoenstatite phase in the preparation of forsterite from magnesite (58wt%) and quartzite (42wt%) at synthesis temperature range of 1500-1730°C.

Foster<sup>5</sup> made a high temperature X-ray diffraction study of polymorphic inversion of MgSiO<sub>3</sub>, which though more relevan to steatite formations has also direct connections to forster formation. According to this scheme, protoenstatite is the stable high temperature phase and clinoenstatite is related to it somewhat as low cristobalite is related to high cristobalite. Foster's scheme of polymorphism and the earlier reported schemes of Bowen and Schairer (1935) and Thilo and Rogge (1939) are shown in Fig. 1 for comparison. Since protoenstatite has a tendency to disintegrate and simultaneously invert to clinoenstatite while standing at

room temperature, the presence of this phase in forsterite porcelains, except in limited amounts is to be avoided. The phase is stabilised against inversion by (a) the presence of a glassy phase in between the protoenstatite crystals or (b) when the protoenstatite crystals are present in very small sizes and the nucleation rate of the clinoenstatite phase is greatly minimised.

From X-ray and microscopic analysis it was found that for the specimens without additives, the formation of forsterite, which was exothermic was found to set in at about  $1100^{\circ}$ C and complete at  $1400^{\circ}$ C as shown in Fig. 2.

The formation of protoenstatite began from  $1280^{\circ}\text{C}$  by the secondary reaction of  $\text{Mg}_2\text{SiO}_4$  and  $\text{SiO}_2$ . In the specimen with the addition of 5% kaolin (PSF-0) which was sintered at  $1460\text{--}1500^{\circ}\text{C}$ , the phases forsterite, protoenstatite, clinoenstatite,  $\alpha\text{--quartz}$  and periclase, as in Fig. 3 were found. In the specimen with 5% kaolin and 10% BaCO<sub>3</sub> (PSF-B) which sintered at  $1300\text{--}1420^{\circ}\text{C}$  as in Fig. 4, the phases forsterite,  $\text{BaO}\cdot\text{SiO}_2$ ,  $(\text{BaO})_2(\text{SiO}_2)_3$  and BaO glass were found. The dielectric losses at 1 Mc/S of both specimens as in Table 4 were low and at 1 Gc/S the loss of PSF-0 was smaller than that of PSF-B.

As practical compositions, the forsterite porcelains were also made from sea water magnesia and sileceous stone instead of from pure  $Mg(OH)_2$  and silica. The base composition

was the same as the earlier one, but the additives were  $\mathrm{BaCO}_3 \cdot \mathrm{ZnO}$  and  $\mathrm{CaO} \cdot (\mathrm{B}_2\mathrm{O}_3)_2$  glass. The latter were added to the base batch in 5% and 10% by weight and a blank base batch was also made ready. The seven kinds of batches thus prepared were calcined respectively until forsterite forming reaction was completed. They were ground with additional 5% kaolin and fired at various temperatures. It was found that the additives such as  $\mathrm{BaCO}_3$ ,  $\mathrm{ZnO}$  and  $\mathrm{CaC}(\mathrm{B}_2\mathrm{O}_3)_2$  glass had a favourable effect of reducing the dielectric loss of the fired specimen, especially the addition of  $\mathrm{BaCO}_3$  was most effective. However, heating in  $\mathrm{H}_2$  at  $\mathrm{1300}^{\circ}\mathrm{C}$  showed easy evaporation and reduction and hence for vacuum tube work the additives were not recommended.

Hayami and Ogura studied the kinetics of formation of forsterite from MgO and enstatite and Hayami studied the reverse case of formation of enstatite from forsterite and SiO<sub>2</sub>. The first study was of development of forsterite by solid state reaction in mixed powders of MgO and enstatite in various mole ratios in temperature range of 1100-1300°C and times of 100 hrs, followed by quantitative X-ray diffraction measurements. Powders used were coarse particles (10 micron) of one component in a fine grained (one micron) matrix of the other component. The results were shown to agree with Ginstling-Brounstein equation. Reaction rate constants were determined and activation energies in range

of 100-110 kcal/mole were obtained. Fig. 5 shows the G-B function  $D(\alpha)$  compared with actual experimental data on forsterite formation.

The second study was similarly of the two component powder system of forsterite and  $\mathrm{SiO}_2$  from which enstatite formation was studied. The fit of the G-B function in the second case was not as good. However, the use of functions related to G-B, showed improved fit. The study indicated the development of enstatite on the forsterite as well as the  $\mathrm{SiO}_2$  side, suggesting that one MgO of (2 MgO) $\mathrm{SiO}_2$  reacts with  $\mathrm{SiO}_2$ . Mg is believed to be the main diffusing species. The results of firing in vacuum suggest that the reaction is possibly controlled by the diffusion of Mg<sup>2+</sup> ion through the enstatite.

Sugiura et al. 9 studied the relation between the microstructure and the electrical and mechanical properties of forsterite. Three kinds of forsterite batches of molar ratio MgO:SiO<sub>2</sub> = 2.00:0.82 (M), 2.00:1.00 (F) and 2.00:1.05 (S) were calcined at 1300°C to which 5/ kaolin was added. The material was fired to various temperatures. Firing shrinkage, apparent specific gravity, water absorption, dielectric loss, insulation resistance and bending strength of the fired specimen were measured to discuss the relation between the properties and the microstructure.

Above physical properties gave the maximum or minimum values at certain firing temperatures. The specimen M fired at 1550°C, F at 1390°C and S at 1370°C gave the maximum values of firing shrinkage, apparent specific gravity, Te value of volume resistivity, and bending strength and the minimum values of water absorption and dielectric loss. At these maximum or minimum points, each specimen showed a similar microstructure being composed of forsterite crystals of about 10 microns. The texture was dense but was not of the perfect mosaic structure that is obtainable by firing at higher temperatures through the rapid growth of the forsterit crystals. It was suggested that the best composition lay between M and F.

The effect of kaolin addition was studied by Sano et al. 10 The stability of forsterite porcelain at high temperatures in hydrogen atmosphere, which is an applicational requirement, is improved by kaolin. Zero to 10 % kaolin was added to forsterite which was prepared from Fukushima sileceous stone and sea-water magnesia in the molar ratio of MgO:SiO<sub>2</sub> as 2:1. The temperature range for the sintering of forsterite was extended remarkably by the addition of kaolin and the firing shrinkage was almost constant within this range. The coefficient of linear thermal expansion decreased with the increase of added kaolin, and no significant change was found by repeated heat treatments. With the

addition of 5% kaolin, the dielectric constant and dielectric loss were unvaried and these values were excellent for a high frequency insulator. The result of X-ray diffraction gave only the pattern of forsterite. By microscopic observation the forsterite crystal grains changed from allotromorphic to idiomorphic and glass matrix increased with the kaolin content.

Table 5 gives dielectric properties of specimens fired at different temperatures.

Sugiura et al. 11 studied the relationship between the microstructure and the thermal expansion of forsterite porcelains. The thermal expansion of forsterite porcelain, which is one of the most important properties for use in electron tube, and the effect of different firing temperatures plus that of repeated heating cycles were investigated. The coefficient of linear expansion along each axis of synthesised forsterite were measured by X-ray giving a=10.47, b=12.50 and c=11.05 x 10<sup>-6</sup> along the respective axis in the temperature range of 20 to 800°C.

Referring to the data of Navais<sup>1</sup> it was pointed out that the elevation of the firing temperature by 25°C would result in an increase of the thermal expansion coefficient by 1.0xl0<sup>-6</sup>, a value considered too high for vacuum sealing purposes with metal. To study this phenomenon many batches of forsterite porcelain were prepared and fired at different

temperatures. The specimens made of talc, sea-water magnesia and  $\mathrm{BaCO}_3$  showed the marked decrease of the coefficient (about  $\mathrm{1xl0}^{-6}$ ) with the elevation of firing temperature from 1400 to  $\mathrm{1500}^{\,0}\mathrm{C}$ . Microscopic observation indicated the increase of glassy phase which has probably the cause of reduction of the expansion coefficient.

The thermal expansion coefficient of specimens containing MgO and  $\mathrm{SiO}_2$  in various ratios have also been measured. Forsterite porcelain having excess of  $\mathrm{SiO}_2(\mathrm{SiO}_2$  47%) showed the increase of the coefficient by about  $1.2\mathrm{xlO}^{-6}$  by the elevation of the firing temperature from  $1400^{\circ}\mathrm{C}$  to  $1600^{\circ}\mathrm{C}$ . The coefficient however decreased with increase of MgO. The specimens containing excess MgO showed only a small variation. Microscopic observation of the specimens containing excess  $\mathrm{SiO}_2$  showed an excessive growth in crystal size of the forsterite when the firing temperature was elevated and the coefficient increased as reported earlier. The samples with excess MgO did not show any grain growth and also the expansion coefficient did not change much.

For a number of compositions, the effect of repeated heatings at lower temperature (1000°C) after firing at higher temperatures, were studied. The results could be classified into two groups. The one in which the coefficient increased and the second group in which it did not change as much. The former had more glass phase under the microscope. The

authors confirmed that the composition of forsterite porcelain for use in electron tube should have excess MgO and the glassy substance should be reduced as far as possible.

Singer and  $\mathrm{Adolf}^{12}$  reported preparation of a forsterite composition matching that of Titanium metal. A prefired mixture of MgO and  $\mathrm{SiO}_2$  in the same proportion as in forsterite, together with 15 //clay or 10 //  $\mathrm{Al}_2\mathrm{O}_3$  gave a ceramic with the required thermal expansion.

A French patent 13 reports the preparation of crystalline  $2\text{MgO}\cdot\text{SiO}_2$  by the low temperature firing of amorphous  $\text{SiO}_2$  and MgO. Thus 30-60 / by weight of dry wet-pptd. silica and 40-70 / of MgO was calcined at 900-1000  $^{\circ}$ C [or Mg(OH)  $_{2}$ /MgCO  $_{3}$ ] and ball milled for 24 hours with water. The mixture was dried at 100°C and sieved (100 mesh). Then 12% by weight of organic binder (ceresine) was added. The mixture was sieved again and molded at 1000 kg/sq.cm pressure. The compacts are then baked for 1 hr at 1450°C in a continuous kiln so that the material temperature was raised by 75°C/hr to remove organic binder and water. A transluscent crystalline forsterite porcelain is obtained in which the tanô was 5x10<sup>-5</sup> while the dielectric loss of the previous ceramic was  $2x10^{-3}$ . The coefficient of thermal expansion of  $9.46x10^{-6}$ could be adjusted to match that of glass by varying SiO2/MgO ratio. The coramics were used in radio tubes, condensers and insulators.

General Electric of U.K. 14 reported the production of a forsterite ceramic matching the thermal expansion coefficient of Ti. The material was especially useful for making envelopes of vacuum tubes.

Soga and Anderson determined the thermal expansion coefficient of forsterite upto  $1000^{\circ}\mathrm{C}$ .

Kanchin and Amburz<sup>16</sup> determined  $\alpha_{20-1000}$ °C of (2Mg0)SiO<sub>2</sub> = 12.2 x 10<sup>-6</sup> per deg.°C.

Smoke<sup>17</sup> reviewed 23 years of dielectric research in Rutgers State University describing studies on loss characteristics of forsterite among other insulating ceramic materials.

Russian workers Usov et al. 18-20 reported work on Forsterite and related materials for high frequency applications.

# CHAPTER 2 EXPERIMENTAL PROCEDURE

For preparing different types of batches indicated below, the raw materials used were  ${\rm MgCO_3}$ ,  ${\rm Mg(OH)_2}$ ,  ${\rm SiO_2}$ , talc and magnesite. In addition, ball clay and  ${\rm BaCO_3}$  were used as additives in one of the batches. Three batch compositions (A) stoichiometric compositions with  ${\rm MgCO_3}$  and  ${\rm SiO_2}$ , (B) Stoichiometric compositions with  ${\rm MgCO_3}$  and  ${\rm SiO_2}$  and (C) magnesite and talc compositions with additions of ball clay and  ${\rm BaCO_3}$  (listed in table 6) were used.

# 2.1 Raw Materials

Imported grades of MgCO<sub>3</sub>, Mg(OH)<sub>2</sub>, SiO<sub>2</sub> of commercial purity were used. Indigenous grades of talc, magnesite, barium carbonate and an imported grade of ball clay were used. Barium carbonate and unwashed ball clay was used as an additive in batch C. The raw material analysis is given in Table 7.

# 2.2 <u>Material Preparation</u>

# 2.2.1 Weighing

Correct proportions of raw materials were weighed out using a single pan aigital balance for the preparation of the batches.

#### 2.2.2 Mixing and grinding

All mixing and grinaing were done under wet conditions. For grinaing of SiO<sub>2</sub>, MgCO<sub>3</sub>, Mg(OH)<sub>2</sub>, magnesite and talc, high alumina porcelain lined ball mills with alumina balls were used with water as the liquid. Methyl alcohol was used as the liquid for grinaing calcined materials containing MgO.

The raw materials of batch numbers A and B were first mixed and ground for 20 hours for good communition of the SiO2, MgCO3 and Mg(OH)2, particularly the SiO2. Batch A was then dried and calcined and subsequently reground for 4 hrs in methyl alcohol media. Batch B, after first grinding and drying, was forsterised and subsequently reground in two steps since the material had become considerably hard. Firstly, it was ground in a steel pestel and mortar and deironed. Subsequently, it was ground in pot mill for 8 hrs in water. For processing of Batch C material, firstly the magnesite lumps were crushed in steel pestel, deironed and ground in ball mill for 24 hours in water. The minus 325 mesh powder was taken after wet sieving, dried and mixed with talc for 4 hrs in a pot mill. After drying the additions of ball clay and BaCOz was made to make up the compositions shown in table 8 and mixed for 4 hours in pot mill, to obtain the final compositions. All arying was done in a temperature controlled electric oven.

## 2.2.3 Calcination and forsterization

Calcination was done in silicon carbide heated pot type furnace, the materials being kept in hard fired alumina crucibles. The materials were introduced cold and the temperature was brought to the calcination temperature in 6-7 hours. Batch A and B were calcined for 4 hrs at 1000°C, and batch C was calcined for 20 hours at 1150°C. The higher time and temperature was used for batch C as the ground raw material for this was substantially coarser.

Subsequent to calcination the batch B material was also forsterised at  $1355^{\circ}\text{C}$  for 20 hours and reground as noted earlier.

The powder density of the above forsterised material was determined by pycnometer.

# 2.3 X-ray Powder Diffraction

In order to find out the extent of transformation and formation of phases during calcination and forsterisation, powder patterns of calcined powders were taken using GE XRD-6 type diffractometer with CuK, radiation.

# 2.4 Sample Preparation

Samples of all batch materials were prepared for electrical property measurements. The powdered material was mixed with approximately 2 // by wt. of P.V.A. and the powder was

pressed into discs of 5 cm diameter using a hand press at a load of 15000 lbs using a cast iron die. For industrial purposes, 5000 psi is reasonable. Pellets of 0.5 cm diameter were also made for trial runs and also for X-ray analysis.

## 2.5 Sintering

Sintering was done in the pot furnace for the lower temperatures (below 1250°C). A tube furnace and a big box furnace were used for attaining higher temperatures (upto 1400°C). All the three furnaces were silicon carbide heated. Temperatures were controlled by an L and N on-off type controller in conjunction with an oil cooled variac. Temperatures were separately measured with Pt and Pt plus 10%. Rh thermocouples and a potentiometer.

Maximum sintering temperatures possible were determined for different batch materials in trial runs so that no sticking occurred between the disc and the substrates as well as in between the discs. Different types of coarse prefired powders, i.e. alumina, zirconia, magnesia, zircon-sand, silica, calcined mixture of magnesia and silica, soft and hard fired forsterite compositions, and fired coarse powders of the components of batch C were used. The best powders were those of hard fired materials of the same composition as the discs. A few samples were sintered at higher temperatures where sticking had occurred. This was done to obtain a very high density. These samples were separated by a diamond

cutter. For the substrates, alumina discs with a layer of coarse powder noted above were used.

Sintering for batches B and C were done in two steps, i.e. first they were presintered at a lower temperature and then finally sintered to different temperatures and times. Batch A material was sintered in one step to different times and temperatures.

Trial runs for presintering and sintering were taken for all batches to determine degree of densification, hardness (for polishability) and sticking propensities.

During presintering runs and low temperature sintering which was done in the pot furnace, the samples were covered by saggers made of alumina. For higher temperatures, saggers could not be used as the diameter of horizontal tube furnace and height of the box furnace were low.

Batch A was fired for different times and temperatures as shown in table 9. For batch B, small 3/8" dia pellets were placed in the tube furnace at such positions, determined by a profile measurement, which gave temperatures of 739, 946, 1067, 1112, 1151 and 1180 degrees centigrade. They were sintered for 15 hrs and the temperature of 1112°C was selected for presintering after examining the characteristics of the corresponding pellets for its polishability. The presintering temperature of 1125°C and time of 15 hrs was chosen for batch B.

Using the above mentioned procedure, the presintering temperature and time for batch C was determined to be  $1100^{\circ}\text{C}$  and  $4\frac{1}{2}$  hrs respectively. The final sintering temperature and times for batch C were 1150 and  $1200^{\circ}\text{C}$  for 5 hrs. Samples of batch A were sintered at different temperatures (1260, 1280, 1300, 1380 and  $1400^{\circ}\text{C}$ ) for different times (5, 10, 11 and 20 hours). Batch B was studied under presintered condition. Batches  $C_1$ ,  $C_2$ ,  $C_3$ ,  $C_4$  were fired at  $1150^{\circ}\text{C}$  and  $1200^{\circ}\text{C}$  for 5 hours after presintering at  $1100^{\circ}\text{C}$  for  $4\frac{1}{2}$  hrs and subsequent polishing. To obtain highly dense samples batch  $C_3$  was also fired at 1160, 1180, 1200 and  $1220^{\circ}\text{C}$  for 10 hrs.

## 2.6 Polishing

After firing, the discs were polished in a fabricated polishing holder (ref. 23, fig. 6), using a glass plate and 100 mesh and 200 mesh powders (SiC). At first, one surface was polished by hand. The polished side was fixed to the holder with a hardenable resin and the second side was polished down to the required thickness. The sample was removed by treatment with acetone. One sample was polished by 600 mesh powder. Polished samples, were stored in a desicator after washing in acetone and oven drying.

# 2.7 Sample Density

Density was determined by geometrical measurements and weighment using a micrometer and balance respectively. Percent

theoretical density was calculated on the basis of theoretical forsterite density (3.2 gms/cc). Approximate density of each batch was also found out using 'mixture rule' and was denoted as calculated density.

## 2.8 Water Absorption

The standard method of test for water absorption (ASTM Lesignation C373-56) was followed to determine the water absorption of the samples. The water absorption (A) which is expressed as a percentage is given by,  $A = \frac{W-D}{D} \times 100$ ; where D and W are the dry weight and the saturated weight of the sample respectively.

# 2.9 Electroding and Wiring

Four types of electroding were used (i) silver paint, (ii) silver paste, (iii) vacuum deposited aluminum and (iv) aluminum foil. Samples were painted/pasted on both sides. Baking at 150°C in oven was necessary for continuity. It was found that optimum baking time was required to remove all solvent, develop continuity and give minimum values of contact resistance as indicated by the Q-values of the samples. Insulated copper wires, with their insulations stripped were fixed on painted surfaces and further coat of paint was applied for establishing continuity between surface and wires. The wires were held in position by spots of aralaite. In some cases coaxial lead wires were joined to these wires.

The painted samples, henceforth termed as electroded samples, are shown in Fig. 6. Some measurements of electroded samples were directly made between parallel plates without wiring.

#### 2.10 Measuring Methods and Elimination of Errors

The measurement of dielectric constant and Q-factor was done on type 260-AP, Boonton Radio Co. Q-meter in the frequency range of 50 Kc/s to 25 Mc/s. The instrument is basically a resonant circuit from which the values of Q and capacitance of the unknown sample can be directly read on a meter and a dial respectively.

The parallel connection method was used. In this case, the circuit was first resonated, using a type 590-A (Boonton Radio Co.) standard coil of known capacitance, to establish reference values  $Q_1$  and  $Q_1$ . The circuit was reresonated with the unknown forsterite capacitor connected to CAP terminals (fig. 7) and standard coil in its original position. The altered value of  $Q_2$  and  $Q_2$  were noted and the actual values of K and Q of the material were calculated as follows:

$$K = \frac{(C_2 - C_1) t}{A\epsilon_0}$$
 (1)

$$Q = \frac{(C_2 - C_1) Q_1 Q_2}{C_1 (Q_1 - Q_2)}$$
 (2)

where t and A are the thickness and area of the capacitor respectively and  $\epsilon_{0}$  is the permittivity of vacuum.

During measurement of K and Q it has been noted that different type of errors were entering into the results. To eliminate these, measuring methods were subsequently changed. Also to check whether any apparently invisible errors had been introduced or not, variations were done. These errors and their elimination are discussed here along with variation in measuring methods.

## (i) Electrode baking conditions

If the silver paint which is used to electrode the sample is not properly baked the sample under test shows low Q and high K values. Thus the presence of solvent obstructs in getting the actual inherent material property (i.e., K and Q).

To remove this, baking time was varied. The sample was kept in electrically heated oven at a particular temperature for different lengths of time.

# (ii) Lead length variation and electrical shieldings

Electroded samples with leads were used first for measurement of K and Q. Lead length was varied to see whether there is any effect of lead length on K and Q.

Measurements were also done by electrically shielding the samples by putting the sample in a completely closed aluminium box. Electrical shielding of the lead was done by using coaxial wire. Shielding was done to remove any extraneous effect on sample which is found at high frequencies.

Measurements were taken using shield both in grounded and ungrounded condition.

## (iii) Number of leads

The contact resistance has a prominent role in finding out actual Q and K of the material. Use of multiple leads should increase contact area and thereby ensure low contact resistance and at the same time reduce contact inductance effect. This is why measurements were taken using multiple leads though extra capacitance is introduced by its use.

## (iv) Fringe effect

Fringe effect was taken care of in micrometer methods (described later) at later stages using guardrings which was grounded. Measurements were also taken using guardring having the same potential as that of lower electrode.

If the test specimen and guard electrode extend beyond the guarded electrode by at least twice the thickness of the specimen and the guard-gap is very small, the field distribution in the guarded area will be identical with that existing when vacuum is the dielectric. Furthermore, the field between the active electrodes is defined and the capacitance can be calculated with the accuracy limited only by the accuracy with which the dimensions are known.

# (v) Porosity

Samples used for measurements were not completely dense,

i.e. they did not possess zero porosity. We could not reach zero porosity because of firing problems. It is evident that porous material will show a low K value. 27

If some moisture is in adsorbed state in the pores it will show a lower value of Q. For this the samples were always kept in a desicator and also plastic bagged during measurement.

To see whether there is any difference in K and Q values between electroded and unelectroded samples, both of them were used. Reliability of micrometer set up was checked using air.

# (vi) Thickness variation

(a) The capacitance ( $\Delta C$ ) of the sample increases with lowering of sample thickness and thus  $\frac{\Delta C}{C_1}$  becomes high as  $C_1$ 

Variation of sample thickness has two effects.

Q 
$$\alpha = \frac{(C_2 - C_1)}{C_1} \cdot \frac{Q_2}{(Q_1 - Q_2)}$$
 i.e. Q  $\alpha = \frac{\Delta C}{C_1} \cdot \frac{Q_2}{\Delta Q}$ 

is constant at a particular frequency. From equation (2)

as  $Q_1$  is constant for a particular frequency.

Now,  $\frac{Q_2}{\Delta Q}$  must decrease if the ratio  $\frac{\Delta C}{C_1}$  is made higher as Q is a material property. This can only be achieved by decrease of the  $Q_2$  value which in turn increases the  $\Delta Q$  value.

It was found during measurements that some times the reading of  $\Delta$  Q value demands eye estimation. So, if the ratio

- $\frac{\Delta C}{C_1}$  is increased, which can be made close to unity by adjusting frequency, more accurate  $\Delta Q$  value is obtainable and thus higher accuracy can be achieved.
- (b) With decrease in sample thickness the fringe effect decreases and thereby increases the accuracy of the K value measurement.

The different types of measurements performed are listed below.

- (a) <u>Lead</u>: The number and length was varied and also coaxial wires were used.
- (b) Electrode: Both the electroded (wired and unwired) and unelectroded samples were used. Different types of electrodes used were (i) silver painted, (ii) silver pasted, (iii) vacuum deposited aluminum and (iv) aluminum foil.
- (c) <u>Parallel Plates</u>: Both flat and pointed electrodes were used (Fig. 8).
- (d) <u>Cell</u>: Capacitance cells were designed in accordance with ASTM standards (D150-65T). The errors caused by the series inductance, capacitance and resistance of the connecting leads at high frequencies are eliminated by this micrometerelectrode method. It accomplishes this by maintaining these inductances, capacitances and resistances relatively constant, regardless whether the test specimen is in or out of the circuit. The specimen, which is either the same size as, or

smaller than, the electrodes is clamped between the electrodes. It is stated that unless the surfaces of the specimen are lapped or ground very flat, metal foil or its equivalent must be applied to the specimen before it is placed in the electrode system <sup>28</sup>.

The arrangement of the ungrounded and unshielded cell is shown in Fig. 9. The experimental variations done in this cell were (i) change of air gap to see fringe effect on the K and Q values and (ii) variation of air gap with unelectroded and electroded sample in series with the gap.

One more capacitance cell (Fig. 10) was designed in which a guard ring was properly placed and complete electrical shielding was ensured (using an aluminium box). Short shielded leads were also used. These were done to minimise extraneous effect. The variations employed were (i) use of only air (ii) use of electroded sample and (iii) use of unelectroded samples.

Measurements were taken with,

- (i) Guardring having the same potential as that of lower electrode.
- (ii) Unguarded, shield grounded.
- (iii) Unguarded, shield ungrounded.
- (iv) Guarded, shield grounded
- (v) Guarded, shield ungrounded.
- (vi) Upper electrode soldered, unguarded, shild grounded.
- (vii) Ungrounded, unshielded.

In all these measurements in capacitance cell it was observed that the inherent capacitance of the cell itself had been giving much trouble for finding out the actual K and Q values of the material. To minimise this inherent capacitance a new cell was designed with minimum amount of dielectric material used. The feature of this cell was the same as shown in Fig. 10 with a few differences which were as follows:

- (i) Structure was of aluminium plate which itself had acted as a shield.
- (ii) Both the lower electrode and the guardring were placed on alumina setters fixed by araldite. This was done to disconnect the lower electrode, and the guardring from the body.
- (iii) The diameter of the lower electrode was made smaller than that of the smallest sample. This was done to ensure proper guard action.
- (iv) A glass tube was used to insulate the micrometer so that it could not touch the body.

This cell was used in (i) guarded, shield ungrounded, (ii) guarded, shield grounded, (iii) guarded, shield with micrometer cap grounded, and (iv) guarded, shield with micrometer cap ungrounded conditions.

Finally, the measurement with electroded and wired (short single lead) samples were adopted as the extraneous effect was unremovable with cell measurements.

#### CHAPTER 3

#### RESULTS AND DISCUSSION

### 3.1 Processing

### 3.1.1 Raw materials

The analysis of  ${\rm MgCO}_3$ ,  ${\rm SiO}_2$ , talc, magnesite and ball clay is given in table 7.

### 3.1.2 Mixing and grinding

All mixing and grinding was done in a potmill using alumina balls as grinding media. Previous work of Das and Gupta showed that assuming wear conditions with ferrite charge no more severe than empty ball load, the contamination level in the alumina jar was 0.2% per hour. The contamination per 1000 gmsballs per hour was 0.484 gm. For our case the contamination will be about 0.25% of alumina per hour as ball: material ratio was 5:1 in comparison to 4:1 for Das and Gupta's case.

# 3.1.3 Calcination and forsterization

The object of calcination was to remove CO<sub>2</sub>, structural water and any other volatile matter (if present) from the raw materials. During decomposition of the raw materials, the particles would become finer. Finer particles are expected to improve sintering.

Forsterization was done at 1355°C for 20 hours as this was the maximum attainable temperature which was imposed by the inherent limitation of the furnace available at that time. The extent of forsterization will be discussed later (3.2).

## 3.1.4 Sample preparation

Big samples of 5 cm diameter were pressed at 5,000 psi and small samples of 0.5 cm diameter were pressed at 18,000 psi. The green densities of the samples are shown in tables 8, 9 and 10. The green densities of big samples are found lower than those of small samples. This is because of the lower applied pressure during forming of large samples. The limitation imposed by the press capacity (15,000 lbs) had prevented the use of higher pressure on the large samples. In commercial practice, however, pressure generally does not exceed 5,000 psi.

Among all the small pellets of talc-magnesite composition (table 8), the batch  $\mathrm{C}_2$  shows highest green density (1.96 gms/cc) and the batch  $\mathrm{C}_4$  shows the lowest (1.63 gms/cc). Packing efficiency increases with increase in number of size fractions, i.e. if 3 size fractions are used in place of 2 size fractions. Both ball clay and  $\mathrm{BaCO}_3$  were used as additives for making batch  $\mathrm{C}_2$  whereas there was no additive for the batch  $\mathrm{C}_4$ . Number of size fractions being more in the batch  $\mathrm{C}_2$  and also higher density of  $\mathrm{BaCO}_3$  (4.43 gms/cc) had increased the green density. The green density of batch

 ${\rm C}_3$  is more than  ${\rm C}_1$  as the density of the additive (BaCO $_3$ ) which was added to the batch  ${\rm C}_3$  is higher than that of ball clay (calculated density 3.19 gms/cc) which was added to the batch  ${\rm C}_1$ .

Large samples which were pressed at higher pressure show higher density (table 9).

## 3.1.5 Sintering

Results of densification and thermal history have been shown in tables 8-13. The densest samples used for electrical measurement possess an average density of 2.97 gms/cc ( $^{\circ}C_3$  composition). These samples were fired at  $1180^{\circ}C$  for 10 hours. The highest density achieved for batch A is 2.85 gms/cc. It was found for batch  $^{\circ}C_3$  (table 13) that porosity increases with sintering at temperatures higher than  $1180^{\circ}C$  for 10 hours. Bloating is the probable cause for such a behaviour.

# 3.2 X-ray Analysis

ASTM DATA CARDS were used for identification of phases present in the sintered samples. Expected phases were listed first and then the standard lines (as taken from ASTM CARD) were matched with the lines which were found from the X-ray diffractogram of the sintered samples. In the pure system of MgO-Al<sub>2</sub>O<sub>3</sub>-SiO<sub>2</sub> the following main phases can be expected depending on the (a) overall average composition (b) local composition which may vary from the average. The phases are

periclase, forsterite, enstatite, protoenstatite, quartz, cristobalite, tridymite, cordierite, mullite, spinel, sapphirine and corundum. In addition when BaO is present further combination, e.g. barium silicate, barium aluminium silicate, barium magnesium silicate etc. are also possible. Matching was done with all the above phases and all the phases except tridymite, mullite, sapphirine and corundum are found present in the samples.

The thermal history and also densification data (only in table 10) of the samples used for phase identification had already been shown in tables 10 and 11. Stoichiometric MgO-SiO<sub>2</sub> and stoichiometric talc-magnesite were used as batch compositions. Talc-magnesite with additives were also used.

Standard lines of forsterite, periclase, protoenstatite, high form of protoenstatite and clinoenstatite are shown in table 14. In table 15, standard lines of enstatite,  $\alpha$ -quartz,  $\beta$ -quartz,  $\alpha$ -cristobalite and  $\beta$ -cristobalite are shown. Standard lines of low cordierite, magnesium aluminate, barium silicate, barium aluminium silicate and barium magnesium silicate are shown in table 16. In the above four tables only those standard lines are shown which have the intensity greater than 10%. The d values and intensity of three intense lines of 27 compounds are shown in table 17. These compounds are also checked for identification of the unknown phases of the samples of interest.

In tables 18-25, only 6 higher intensity lines of forsterite are shown in A part and the phases identified as different from forsterite are shown in B part. All unidentified lines are shown separately in table 26. Sometime, it happens that a particular line of the X-ray diffractogram matches with standard lines of several phases due to overlap. These overlaps are also present in tables 18-25.

Table 18 shows X-ray diffraction data of stoichiometric talc and magnesite samples fired at  $1350^{\circ}\text{C}$  (E<sub>1</sub>) and at  $1300^{\circ}\text{C}$  (E<sub>2</sub>) for 10 hours. Forsterite,  $\alpha$ -cristobalite and  $\beta$ -cristobalite lines are identified. For sample E<sub>1</sub>, lines having d values 3.18, 2.91, 2.88 Å and for samples E<sub>2</sub>, 3.17, 2.90, 1.96 Å are matching closely with protoenstatite, enstatite and high form of protoenstatite. It is not possible to say whether these lines are single lines or overlaps. No MgO line is found though high silica phases e.g. enstatite and also cristobalite are present. Complete forsterization at lower temperature is possible only when excess MgO is present. <sup>7,8</sup> Only one line remains unidentified in sample E<sub>1</sub>.

Table 19 shows X-ray diffraction of samples made of stoichiometric talc and magnesite and sintered at  $1250^{\circ}\text{C}$  (E<sub>3</sub>) and at  $1200^{\circ}\text{C}$  (E<sub>4</sub>) for 10 hours. All lines are identified.

Table 20 shows X-ray diffraction analysis of stoichiometric samples of  ${\rm Mg(OH)}_2$  and  ${\rm SiO}_2$  sintered at  $1315^{\rm O}{\rm C}$  for 20 hours  $({\rm F}_1)$  and at  $1100^{\rm O}{\rm C}$  for  $4\frac{1}{2}$  hours  $({\rm F}_4)$ . Forsterite lines are

identified. Some unreacted SiO, is visible. Protoenstatite, high protoenstatite and low cordierite and magnesium aluminate are also present in the sample  $F_4$ . During grinding, there was  ${\rm Al}_2{\rm O}_3$  pick up ( $\simeq$ 6/) which had reacted with MgO and  ${\rm SiO}_2$ to form cordierite and magnesium aluminate. There was no other source of alumina in the raw materials. Lines of cordierite which have d values 8.50 A and 8.52 A with intensity 100 and 95 respectively are absent as we did not scan up to that a value. No aluminate is present in the sample  $F_1$ . Alumina Which comes during grinding in the potmill is in a very fine form. There is one eutectic point in each of the two triangles formed by cordierite-enstatite-silica and cordierite-enstatite-forsterite at 1345°C and 1360°C respectively. The fine alumina powders which were picked up during grinding and reacted to form cordierite and other aluminates had possibly formed eutectic liquia which had turned to a glassy state during cooling. This is the most probable cause for which there is no trace of alumina in the sample F7.

Table 21 shows X-ray diffraction analysis of stoichiometric  ${\rm Mg(OH)}_2$  and  ${\rm SiO}_2$  sintered at  $1200^{\circ}{\rm C}$  for 12 hours. Only one line remains unidentified in case of sample  ${\rm F}_2$  and none for sample  ${\rm F}_3$ . Forsterite lines are identified. Presence of  $\alpha$ -quartz,  $\beta$ -cristobalite, protoenstatite, enstatite and high protoenstatite shows intermediate reaction between MgO and  ${\rm SiO}_2$ . Hayami had reported that the rate of reaction

of the systems containing MgO and  $SiO_2$ , i.e.  $MgO-SiO_2$ ,  $MgO-MgO\cdot SiO_2$  and  $2MgO\cdot SiO_2-SiO_2$ , is conceivable to be controlled by the diffusion of Mg through the product layer (s). Therefore to obtain the full stoichiometric compound of  $2MgO\cdot SiO_2$  higher temperature or longer times are necessary, failing which intermediate phases are expected to be present. Lines having d values 3.02 Å  $(F_2)$  and 3.01 Å  $(F_3)$  are identifiable as that of low cordierite. Lines of cordierite having d values 8.50 Å and 8.52 Å are not visible as we did not scan upto that d value.

X-ray analysis of two samples  $G_1$  and  $G_2$  which are formed from stoichiometric talc, magnesite with additives and sintered at  $1100^{\circ}$ C for  $4\frac{1}{2}$  hours is shown in table 22. Along with forsterite,  $\alpha$ -quartz,  $\alpha$ -cristobalite, protoenstatite, enstatite and high protoenstatite are present. Lines having d values 3.05 Å and 2.39 Å of sample  $G_1$  are identified as low cordierite and magnesium aluminate respectively. The same argument as given for sample  $F_4$  is also applicable here to justify the presence of cordierite. Other intense lines of magnesium aluminate which have d values 1.43 Å and 2.01 Å with intensities 100 and 70 respectively have overlapped with the nearest lines of the sample. The line having d value 2.39 Å of sample  $G_1$  is also matching with the corresponding line of gamma alumina; but it was discounted since alumina is guite reactive with forsterite. In sample  $G_2$ 

seven parts of  $\mathrm{BaCO}_3$  and four parts ball clay were added during preparation. Barium silicate, barium aluminium silicate and cordierite are present in sample  $\mathrm{G}_2$ . Other lines of barium silicate and barium aluminium silicate are overlapping with that of forsterite. Alumina which was picked up during grinding and also ball clay were the source of  $\mathrm{Al}_2\mathrm{O}_3$  during formation of barium aluminium silicate.

X-ray analysis of sample  $G_3$  and  $G_4$  which had been formed from stoichiometric talc, magnesite with additives and sintered at  $1100^{\circ}$ C for  $4\frac{1}{2}$  hours is given in table 23. Periclase line (2.11  $\stackrel{\circ}{A}$ ) is found in sample  $G_4$ . In both the samples  $\alpha$ -quartz, protoenstatite, enstatite and high protoenstatite are present. Barium silicate, barium magnesium silicate are found in sample  $G_3$ . Other lines of barium silicate and barium magnesium silicate are indistinguishable due to overlap. Barium carbonate was added to sample G3 and had acted as a source of BaO for forming barium compounds. Three lines of sample  $G_3$  remain unidentified. All the lines of sample  $G_A$ are identified. Phases containing alumina are not found in the sample  $G_4$ . The explanation given for sample  $F_1$  for the absence of phases containing alumina by formation of glass at  $1345^{\circ}$ C and  $1360^{\circ}$ C is not valid here as the sample G<sub>4</sub> was sintered at only  $1100^{\circ}$ C for  $4\frac{1}{2}$  hours.

X-ray diffraction of forsterite composition of stoichiometric talc-magnesite With adultives is shown in table 24. Both the samples  $\mathrm{H_1}$  and  $\mathrm{H_2}$  were fired at  $1200^{\circ}\mathrm{C}$  for 5 hours. All the lines are identified. Barium magnesium silicate is found present in the sample termed  $\mathrm{H_2}$ . Few lines are also matching with protoenstatite, enstatite and high protoenstatite. Other intense lines of barium magnesium silicate are indistinguishable due to overlap. No phase containing alumina is present in both the samples  $\mathrm{H_1}$  and  $\mathrm{H_2}$ . The same argument of glass formation as given for sample  $\mathrm{F_1}$  is also applicable here. Ball clay being present in both the samples has lowered down the liquid formation temperature. Hence, although the samples  $\mathrm{H_1}$  and  $\mathrm{H_2}$  were treated at a much lower temperature (1200°C) than that of sample  $\mathrm{F_1}$  (1355°C) the glassy phase could have formed in these samples.

X-ray diffraction of sample  $H_3$  and  $H_4$  which were formed from stoichiometric talc-magnesite with additives and were sintered at 1200°C for 5 hours is given in table 25. Periclase is present in both the samples. Sample  ${\rm H}_{\rm S}$  shows presence of cordierite and magnesium aluminate. Barium carbonate was added in the sample  $H_3$  as additive. Here the possibility of forming glass from aluminate and cordierite is very less as BaO always acts as a devitrifier. Cordierite is present in sample  ${\rm H}_{\!\varLambda}\,.$  Both the samples  ${\rm G}_{\!\varLambda}$  and  ${\rm H}_{\!\varLambda}$  were prepared from same batch composition (stoichiometric talc-magnesite) and sintered at two different temperatures, viz.  $1100^{\circ}$ C (G<sub>A</sub>) and  $1200^{\circ}$ C  $(H_4)$ . Free silica which was present in the samples made of pure material (F1, F2, etc.) was absent here as talc and magnesite did not contain any free silica. Perhaps alumina does not react with a silicate so easily as it reacts with free silica. This is the most probable cause for which phases containing alumina was not found in the sample  $\mathbf{G}_{\mathbf{A}}$  which was fired at a lower temperature (1100°C). At higher temperature (1200°C) appreciable reaction had taken place and cordierite was formed.

In ref. 6 it is stated that in forsterite samples prepared with BaCO<sub>3</sub> additives, enstatite phases disappeared at higher temperatures (Figs. 2, 3 and 4) when compared with those of clay additives. In this experiment, however, sintering was

carried out below 1200°C for 5 hours. Both the lower sintering temperature and different base material (i.e. talc-magnesite as against pure components in ref. 6) may explain this difference of presence of enstatite.

It may be observed that a number of lines which remain unidentified from all the samples are shown in table 26.

## 3.3 Errors in Electrical Measurements

Measurements of K and Q were performed in different conditions to eliminate possible errors. Q values obtained in these measurements are found lower as compared to the values of similar materials reported in literature.

## 3.3.1 Electroded and wired sample

Table 27 shows K and Q values of electroded forsterite samples using two connecting leads on each face (Fig. 6). The K values have an average variation of 6%. Though there is a wide scatter of Q values between frequencies, it has got an increasing trend from lower to higher frequencies. Sample I and II have shown before (ref. 22, table 8) higher Q values, ranging from 461-1514. Probably overbaking of silver paint has occurred which has brought down the apparent Q of the material.

## 3.3.2 Variation of number of leads and lead length

Table 28 shows some difference in Q value with multiple leads over one lead (column 3 and 5). Best Q values are

obtained from multiple lead assembly. Use of one lead shows lowest Q value. Intermediate Q value is obtained when one lead but multiple junction is used. The K values are close to reported data's of forsterite. Later on multiple leads were not used to minimise stray wire capacitance and also for practical problems as written earlier.

Table 29 shows that different lead length do not cause any significant change in Q values. The K values are lower due to low density of the sample (approximately 64/as compared with about 85-89 / of sample numbers I to VIII). In later measurements short leads were used to minimise extraneous effect.

Table 30 shows K and Q values of unguarded, electroded and single wired forsterite samples in a frequency range of 55 Kc/S to 8.3 Mc/S. The K and Q values can be taken as constant over the entire frequency range. The average K and Q values are 4.9 and 304 respectively. The percent theoretical density of the sample is low (only 62.5%) which leads to lower K value.

Table 31 shows K and Q values of forsterite samples which were sintered at  $1150^{\circ}$ C and  $1200^{\circ}$ C for 5 hours. Effect of different baking time on K and Q values are observed to confirm earlier suspicion that improper baking shows lower Q reading. Silver paint obtained from NPL were used. According to the instruction sheet for this paint, the samples

should be kept at  $150^{\circ}\text{C}$  for 2-3 hours for proper baking. Samples used after 90 minutes baking at  $150^{\circ}\text{C}$  shows higher K and lower Q value than that used after 150 minutes baking at  $150^{\circ}\text{C}$ . Samples of batch  $\text{C}_1$ ,  $\text{C}_2$  (fired at  $1150^{\circ}\text{C}$ ) and  $\text{C}_4$  show low K values (2.7-5.0) which is due to low density of the samples.

More experimental variations that had already been shown and discussed in ref. 23 are not discussed here as either there is no relevance with the final action or those are mere repetition.

# 3.3.3 Electroded samples between parallel plates

Fig. 8 shows arrangement for clamping electroded samples between parallel conductors which is a standard procedure for measurement of capacitance and dielectric constant of disc samples.

Table 32 shows results of discs between parallel plate and table 33 between clamps with smaller but firm contact. The samples were same wired samples (used before) with contact made directly on electroded faces. Here the reported K values are not the actual k of the material. The capacitance values used for calculation includes another component - air capacitance which was in parallel with the sample. This air capacitance arose from the fact that about 1 cm x 1 cm conductor surface remained bare when the sample was introduced between the parallel conductors.

The area of the sample was about 9 sq.cm and the dielectric constant of the forsterite samples was about 6. The area of the aircapacitor was about 1 sq.cm and dielectric constant 1. For table 32 the thickness of aircapacitor was that of the sample and for table 33 it was about 0.6 cm, i.e. about 3 times larger than that of the sample. Thus the actual K value of the samples will be about 2 / less than the K value shown in table 32 and 0.6 / less for table 33. These set ups were never used in future because of the wide and irregular variation in Q values.

The broad conclusion on above measurements are as follows:

- (i) Electroded and wired samples show higher Q than electroded samples clamped between plates or sharp contacts.
- (ii) Change of lead length within small limits has no effect on measured Q values.
- (iii) Multiple leads improve Q, but need not be used to minimise extraneous effect.

# 3.3.4 Measurement with capacitance cell

Measurement of K and Q were first taken with an unshielded capacitance cell (fig. 9).

Table 34 shows K and Q values of air when airgap is varying from 0.5 cm to 0.025 cm. An ideal air capacitor should show K value close to unity. Here K approaches to unity with decrease of thickness. This is probably due to

end effects. The end effect depends on (a) the thickness (t) of the capacitor as well as (b) the K of the medium. Higher values of t will increase apparent values of K measured. On the other hand, higher effective values of K will reduce fringe effect. The Q values are high and consistent with that of air which should show high Q. At higher frequencies the effect on K is higher which is not unexpected.

In Ref. 28 it is stated that both unelectroded or electroded sample may be placed in a cell for measurement of capacitance.

Table 35 shows comparison between unelectroded and electroded sample. The K values at each step were not calculated as it was a composite capacitor of air and material. The total capacitance values at each step were available. For the unelectroded sample the Q values went on dropping as the air gap between parallel disc conductors and the disc sample was reduced until it reached a very low value of nearly unity when the sample was touched by the conductor plates. But with an electroded sample the variation of air gap had no effect. This experiment was not reproducible later with another cell and reason for this was also not found.

Table 36 again gives similar comparison. The Q value was unmeasurable when the measurement was taken with the

unelectroded sample in touched condition. The sample with better baked electrodes shows higher Q, although overbaking, as remarked earlier, leads to reduction of the Q value. The same sample was used before (table 30). The K and Q values of the sample with better baked electrodes are comparable with that at 55 Kc/S of table 30. The K value (4.61) is low as the sample was porous (62.5 // theoretical density).

Measurement of  $\triangle$ C, K and Q values were performed, which had already been reported in ref. 23, table 40 and table 41, with the samples XIII and XIV which were used in tables 35 and 36, after lowering down their thicknesses. The Q values did not vary much as was expected. Thin samples are supposed to give more accurate results as discussed earlier.

The broad conclusion from the unshielded and unguarded cell measurements are:

- (1) Unelectroded samples give very low Q value.
- (2) Q values of electroded samples when tested in cell are similar to those tested by Wiring.
- (3) Baking characteristics of electrodes have significant effect on Q values measured.
- (4) Higher porosity samples give lower Q values.

Table 37 shows K and Q values of air as measured by the shielded and guarded capacitance cell. Here Q values are very low as compared to Q values of air as found before.

obtained in ungrounded and unshielded condition. From now onwards 'unshielded condition' actually means shielding in unearthed condition. But these values are also much lower compared to the previous results. The probable cause is change of design and higher humidity in August. Previous air capacitance values were taken during dry summer whereas these measurements were taken during monsoon. The K values are also higher as compared to previous values, though the trend is not as high as found before. Here also K is decreasing with decreasing airthickness. Lowering of fringe effect can explain this behaviour.

In table 38,  $\triangle$ C, the total capacitance of cell and Q are measured. From the data it is clear that with decrease of air thickness capacitance of air does not increase proportionally. It is possible only if the capacitance of the cell itself and that of the circuit have already been introduced in the air capacitance. The capacitance of dielectric is given by:  $C = \frac{A}{t} K \epsilon_0$ , where A is the area of the capacitor (dielectric), t is its thickness,  $\epsilon_0$  is the permittivity of a vacuum and K is the/permittivity of the dielectric. The measured capacitance contain two components, inherent capacitance of the cell  $C_C$ , which can be taken as constant and the capacitance of dielectric  $C_D$ , which depends on the geometric factor A/t. Let  $C_T$  be total

capacitance of the cell consisting of the two components. Then.

$$C_{T} = C_{C} + C_{D}$$

$$= C_{C} + \frac{A}{t} \times \epsilon_{O}$$

 ${}^{\circ}$ . If  ${}^{\circ}$  Is plotted against A/t, K can be found out from the slope of the straight line provided the above linear relationship is valid.

Fig. 11 shows total capacitance versus A/t plot. From the figure it is seen that the plot is not a straight line but a curve. Here also the slope of the curve at different points is equal to  $K\epsilon_0$ . For clarification calculation is given below for 3 points.

Point A: 
$$C_T = 132.7 \text{ pf}, \frac{A}{t} = 745 \text{ cm}; \text{ ... } K = \frac{\text{Slope}}{\epsilon_0} = \frac{\frac{71}{745} \text{xloo}}{8.854}$$

Point B : 
$$C_T = 80.7$$
 pf,  $\frac{A}{t} = 353$  cm,  $K = \frac{\frac{46.8}{353} \times 100}{8.854} = 1.5$ 

Point C : 
$$C_T = 27.3 \text{ pf}, \frac{A}{t} = 18 \text{ cm}, \therefore K = \frac{\frac{2.6}{18} \text{x}100}{8.854} = 1.6$$

It is clear that more accurate value of K is obtained at lower thickness. In the above consideration the fringe effect, has not been taken into account. The fringe effect, which is higher for greater thickness of the capacitor, leads to higher K value for thicker air capacitor than the thin one. In early measurements (Table 31) the same observation, i.e. increase of K value with increase of capacitor thickness was found.

Table 39 shows AC the net capacitance of cell and Q value of air using capacitance cell. For all the conditions the trend of Q value is same. Q is decreasing with increase in air gap as was seen in earlier measurements. not increased proportionally as gap is decreased, surely some inherent capacitance of the cell and that of the circuit are present. This capacitance value should be deducted from the  $\triangle$ C value curing calculation of K of air. The same procedure as adopted for the previous experiment is also applicable here for elimination of extraneous effect, i.e. by plotting total C versus A/t and taking K from the slope of the curve. The  $\triangle$ C value is always higher in shielded condition than that in unshielded condition. It points out that inherent capacitance is higher in shielded condition. (Fig. 10) Use of pinconductor/has not changed the C or Q value to a large extent. The assembly with shield in unearthed condition gives lower K value and external effect is less. standard coils also the shiclds are not earthed. In ref. 28 it is stated that the shield can also be connected with the guardring which is earthed. The above two statements are anomalous. In the capacitance cell (1690 A) which is used for lower frequency and is a standard spare for the Boonton Q meter, the shield is earthed. According to the measuremen+ performed it can be stated that assembly with shield earthed should not be used for high frequencies.

In table 40, K and Q values of unelectroded, unguarded forsterite sample are given. The K value is closer to the expected value ( $\simeq$ 6) in shielded condition. The Q value is decreasing With decrease in air thickness. In Q values a peak at 0.300 cm is seen. It points out that only one mechanism (either series or parallel inherent capacitance) is not active. In arrangement 2B,  $\triangle C: C_1$  ratio was made high by adjusting frequency. Increase in  $\triangle Q$  value occurs at such condition for balancing the increase in \( C:C1\), ratio and this riangle Q is more reliable than that in arrangement 2A. It must be noted that in previous experiments very low Q values were obtained when unelectroded samples were used in touched condition. But here the & values are appreciable. The K values are taken only in touched condition as in other positions of the conductor plate it was forming a composite capacitor of air and the disc sample.

In the measurements as described in table 39 and table 40 guardring was not used as the guardring was not helpful in the earlier measurements. For a proper guarded condition the sample diameter should be greater than that of lower electrode which should be surrounded by guardring. The samples used earlier was smaller than lower electrode which was surrounded by guardring.

To minimise the inherent cell capacitance and also to make an effective guarding a new cell was designed. The

cell being made of metal (aluminium) acts also as a shielded cell but without having any dielectric material inside. Measurements of K and Q of forsterite samples were taken in this cell in four different conditions. Table 41 shows that the Q values are low. The K values are much higher than the expected and the K value increases sharply with increase in sample thickness. Fringe effect increases with the increase in sample thickness and thereby increases the apparent K of the material. The inherent capacitance of the cell itself is also higher which has brought the apparent K value higher.

The cell was originally designed to avoid external influences for Which minimum amount of dielectric material was used. But the external influence which had unexplainably increased the K value was much higher than the previous cells. So, cell measurements were discarded and electroded and wired method was again adopted.

# 3.4 Data on K and Q Measurements

The reported K and Q values of forsterite vary from 6-11.5 and 500-10,000 respectively 1,5,6,10. Both the K and Q value should remain constant in a frequency range upto 10,000 Mc/S as discussed in Appendix II. Peak in tanó may be observed only at very high frequency which is beyond the range of the Q meter.

For porous samples it is expected that both the  $K^{27}$  and  $Q^9$  values should be lower than the reported values of samples which were completely dense.

The average K and Q values obtained for the densest sample (93 / theoretical) made of stoichiometric talc-magnesite with 7 parts of BaCO<sub>3</sub> additive are 6.63 and 2074 respectively in frequency range of 100 Kc/S-25 Mc/S. For pure forsterite samples of 89 / theoretical density the average values of K and Q obtained are 5.55 and 707 respectively. The lower K and Q value is attributable to the lower density of the samples. Sintering of pure forsterite samples at temperature higher than 1400°C for obtaining denser material was not possible because of limitation imposed by the furnace available.

The effect of a particular additive towards the K and Q value was not observable because to attain that objective, the sample should have equal and high densities or else the effect of density and additives would not be separable.

Table 42 shows the average K values of 3 batches fired to different densities. The K value remains constant within the frequency range 70 Kc/S to 11 Mc/S. The K value is higher for higher density samples. During calculation of average K value, the thin samples were only taken into account as it is the thin samples which show more accurate K values.

Table 43 shows K and Q values of electroded and wired forsterite samples. Measurement was done at 6 different frequencies. The variation of the K value with the change of density cannot be predicted here as there is a wide scatter in values ranging from 5.08-7.48. Literature values, as reported earlier, shows higher Q values for higher density samples. Here also the densest material made of talcmagnesite and BaCO<sub>2</sub> shows higher average Q values (2074) than that of lower density material (616). Though the variation in percent calculated density is not much, the above trend is confirmed from water absorption values, which show distinctly that lowest absorption sample give highest Q values. For pure material with 1.07 percent water absorption, the average Q value is 707. So, it can be predicted that samples with zero absorption will show higher Q values than those found in the table.

Table 44 shows the K values of electroded and wired samples with varying thickness. Thicker samples always show higher K values. At high frequencies thicker samples had shown lower K values at some cases (Table 31). The cause of such arop is not understandable. The K values of the samples have been plotted against the sample thicknesses (Fig. 12). There is a flattening trend of the plot at lower thickness. The thin sample shows closer expected K value than that of thick one. The flattening trend and the closer expected K value for thin samples were also observed in Table 31.

Higher apparent K values (6.53-8.39) were observed in earlier measurements (Tables 27 and 28). This was mainly due to under baking and also due to high thickness of the samples. Q values were low in all the earlier measurements (section 3.3) as the porosity of the samples were high. Porous samples also show a lower K value.

#### CHAPTER 4

#### CONCLUSIONS

- (1) Samples of zero porosity is necessary to achieve optimum properties. To achieve zero porosity higher firing temperature is required since longer grinding time is not possible if contamination is to be avoided.
- (2) For complete forsterization higher reaction temperature is necessary.
- (3) Thin samples with well baked and wired (short) electrodes will give accurate value of dielectric constant, K.
- (4) The K values obtained are fairly close to literature.

  Higher values also have been reported in literature.
- that of

  The values of tanδxl0<sup>4</sup> obtained (5-20) are higher than /

  the reported (1-15) in literature. Superior values of

  tanδ can be expected with samples of high density.
- (6) The loss factor (K tanδ) obtained (0.003) for the best sample meets the requirement necessary for insulating ceramics of grade L-6.

#### CHAPTER 5

### SUGGESTIONS FOR FURTHER WORK

- (1) The powder characteristics, pressing condition, sintering time and the temperature can be investigated in order to obtain optimum densification for particular raw materials.
- (2) The effect of different additives may be investigated by obtaining a base material of zero porosity.
- (3) The relationship between microstructure and electrical properties (K and Q values) can be established.
- (4) Other properties of forsterite, e.g. thermal expansion, thermal conductivity etc. may be investigated.
- (5) Electrical measurements in the microwave region should be done.

In fact, a programme is already underway to investigate (4) and (5).

#### TABLE 1

Jan-I-10 Minimum Requirements for Insulating Ceramics, Radio Class L

Porosity:

No liquid penetration at 10,000 psi pressure.

Thermal Stress Resistance:

Type A - withstand 20 cycles from 100°C into 0°C water.

Type B - withstand 5 cycles from 100°C into 0°C water.

Transverse Strength:

Greater than 3000 psi.

Dielectric Strength:

Greater than 180 volts/mil.

Dielectric Constant:

Less than 12 after 48 hr water immersion.

Loss factor (k' tanô):

Grade L-1 < 0.150

L-2 < 0.070

L-3 < 0.035

L-4 < 0.016

L-5 < 0.008

L-6 < 0.004.

CENTRAL HERARY

AGE No. A 58752

TABLE 2
Typical Properties of Steatite and Forsterite

Typical Applications	Steatite	Forsterite
Properties	H.F. Insula- tion Electri- cal appliance insulation	H.F. Insula- tion ceramic- to metal seals
Density (g/cm³)	2.5-2.7	2.7-2.9 <sup>\phi</sup>
Water absorption ( )	0.0	i.0
Coefficient of linear thermal expansion/C	8.6-10.5x10 <sup>-6</sup>	11 x 10 <sup>-6</sup>
Safe Operating temp OC	1000-1100	1000-1100
Thermal Conductivity (cal/cm <sup>2</sup> /cm/sec/C)	0.005-0.006	0.005-0.01
Tensile strength (psi)	8000-10000	10000-15000
Compressive strength (psi)	65000-130,000	60000-100,000
Flexural strength (psi)	16000-24000	18000-20000
Impact strength (ft-lb; 1' rod)	0.3-0.4	0.03-0.04
Modulus of elasticity (psi)	13–15 x 10 <sup>6</sup>	13 <b>–</b> 15 x 10 <sup>6</sup>
Thermal shock resistance	Moderate	Poor
Dielectric strength (volts/mil; 1/4" thick)	200-350	200-300
Resistivity (ohms-cm) $^{\varphi}$	10 <sup>13</sup> -10 <sup>15</sup>	10 <sup>13</sup> -10 <sup>15</sup>
Power Factor (1 Mc)	0.0008-0.0035	0.0003
Dielectric constant	5.5-7.5	6.2-6.6

 $<sup>^{\</sup>phi}$  Theoretical density 5.2 gms/cc.

Forsterite Composition Maturing Around 1250°C (Cone 10) TABLE 3

Composition No.	166	166 166E	190-1V	190-1B	190-1A 190-1B 190-1C 190-WA 190-2B 190-2C	190-wA	190-2B		190-34 190-3B	190-3F	190
Sierramic talc	84	80	70	09	50	70	09	50	09	50	51.8
Mg(OH)			15	25	35	10	20	30	15	25	35.2
$\mathrm{BaF}_{2}$	10	10	10	10	10	10	10	10	10	JC	J.C.
Kentucky Ball Clay No. 4	<b>1</b>	_			•	7	7	7	10	10	
Bentonite	10	23	2	2	7	2	<u>ا</u>	3	5	5	
	100	100 100	100	100	100	100	100	100	1.00	100	100
Fired in air Conc (tunnelkiln)	10	10	10	10	10	٦c	10	) T	70	) 10	10
Water absorption percent		0	0	0	3.35	) 	<b>O</b>		0.1	0	6.0
3 cm wavelength K PFx 10-4	6.15	6.15 6.30 15 20	6.34	6.11	1	6.39	6.35	6.29	t i	1 1	6.34
A TAMAS AND THE PROPERTY OF TH	AND BRADER - ARDER NO	Buches, billion & Service Street	real or the highest residence of the complete control of the contr	TEXAS VARIABLE PARKET AND REPORT FOR		ALTONIA CONTRACTOR CONTRACTOR PROPERTY AND	e Principal de l'Ambre	pe Pro John V. Verschelder signification provide upo	- Part - January Supplement	AND THE MENT OF THE PROPERTY OF THE PARTY OF	STATE OF THE PERSON NAMED AND ADDRESS OF THE PERSON NAMED AND

(After Ref. 1 Table XXII.)

TABLE 4

Lieloctric Properties at High Frequencies (After Ref. 6, table 3)

No.	l Mc/s tanδ x 10 <sup>4</sup>	ε	10,000 Mc/s tanô x 10 <sup>4</sup>	ε
PSF-0	3	6	6	6
PSF-B	. l	6	12	6

TABLE 5

Lielectric Properties of Samples of Stoichiometric Forsterite Plus Additions of Lifferent Percentage of Korean Kaolin: FK-0 (F 100 K 0), FK-1 (F 97.5 K 2.5), FK-2 (F 95 K 5), FK-3 (F 92.5 K 7.5) and FK-4 (F 90 K 10). (After Ref. 10, Table 6)

Specimen	ε	and tanô (x10 <sup>-4</sup> )	Firin 1370			pecime		1610
	ε	50 KC/S		6.6			8.4	
FK-O		l MC/S		7.2	8.0	8.2	8.2	11.2
	tanô	50 MC/S l MC/S		13 3	1	1 2	3	1 2
FK-l	ε	50 KC/S l MC/S	7.6 7.6			8.1 8.0		
T. WT.	tans	50 MC/S	1	1	1	1 1		
FK-2	ε	50 kC/s l kC/s	7.7 7.8	8.0		8.1 7.0		
•	tanô	50 KC/S 1 MC/S	1 2	1 2	1 2	1		
FK-3	ε	50 KC/S l MC/S	7.5 7.5		7.3 7.7	7.5 7.4		
F.K-7	tanò	50 MC/S l MC/S	6		4 3	5 5		
FK-4	ε	50 kc/s 1 kc/s	7.3 7.9					
	tanδ	50 KC/S l MC/S	9 6	6 9	1 2	5 6		

TABLE 6
Composition of Various Batches of Forsterite

	Ingredients
MgCO <sub>3</sub> + SiO <sub>2</sub>	Stoichiometric <sup>*</sup>
Mg(OH) <sub>2</sub> +SiO <sub>2</sub>	Stoichiometric*
Talc+Magnesite	Stoichiometric*
	Mg(OH) <sub>2</sub> +SiO <sub>2</sub>

<sup>\*</sup>Stoichiometric means MgO: SiO<sub>2</sub>:: 2:1.

TABLE 7  $\label{eq:Analysis} \text{Analysis of MgCO}_3, \ \text{SiO}_2, \ \text{Talc, Magnesite and Ball Clay}$ 

Constituents	MgCO <sub>3</sub>	SiO <sub>2</sub>	Talc	Magnesite	Ball Clay
MgO	42.65	Nil	34.00	47.54	Trace
SiO <sub>2</sub>	0.79	94.50	57.66	0.77	62.06
CaO	0.42	1.04	1.46	1.64	Trace
Al <sub>2</sub> 0 <sub>3</sub> )			1.16	Nil	21.38
Fe <sub>2</sub> 0 <sub>3</sub>	1.40	6.00	2.84	1.60	7.20
TiO <sub>2</sub>			Nil	Nil	Nil
Na <sub>2</sub> 0 and K <sub>2</sub> 0	Nil	Nil	Nil	Nil	8.68
L.O.I,	54.94		1.22	50.80	4)

TABLE 8

Progressive Lensification Lata for Lifferent Forsterite Batches of Stoichiometric Talc-Magnesite Composition

70 27 + 1.00	1 1 2 C C C C	AND COMMENTS OF THE PARTY AND COMMENTS	A CALLED AT LABORATION A CALLED AND A C	AT . THE CHARGE BOOK IS ABSOLUTED ASSOCIATION ASSOCIAT		PARTY OF THE PROPERTY AND THE		". Men . 187 1993 Feb. "Men. 17 für zumahage Getterheinen		MALES SECURED AND AND AND AND AND AND AND AND AND AN
Calcined stoichiometric mixture of talc and magnesite	Ball E	Baco <sub>3</sub> Batch	Batch No.	Sample No.	Actual Temp. Oc	Time Hrs.	Average Green density gms/cc	Fired density gms/cc	Percent theore- tical consity	Percent calculated density
100	4	0	٦	H010/410	1277 1265 1227 1084 878	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	1.83	2.94 2.89 2.90 1.88	000000000000000000000000000000000000	89 87 87 57
100	7	_	S	10W4N	1277 1265 1227 1084 878	=====	1.96	3.01 2.98 2.98 2.11 1.94	90 90 90 19	89 88 88 62 57
700	0	_	G <sub>3</sub>	<b>ころを4万</b>	1277 1265 1227 1084 878		1.95	3.02 3.02 3.00 1.95	94 94 95 61	89 88 62 57
100	0	0	c <sub>4</sub>	10045	1180 1151 1112 1067 946		1.63	2.97 2.84 1.99 1.98 1.89	93 62 62 59	89 85 60 59
						Miles de la company de la company de	AND THE PROPERTY OF THE PROPER	ARTHOUGH COMPANY AND A TAKE A	e despesable es espanentalmentalmente es especialmente en especialmente en especialmente en especialmente en e	The Marie of the Capital of the Capi

Pressure applied = 18,000 psi.

Densification and Thermal History of the Forsterite Samples Used for Electrical Measurements TABLE 9

e t s tea	Bridge Commence of the Commenc				A constitue and the constitue of	M Marricha
Average percent calculated density	88	84	88	85	64	59
Average percent theore- tical density	89	85	83	36	64	6.3
Average fired density gms/cc	2.84	2.71	2.85	2.75	2.06	2.00
Average Green density gms/cc	1.01	1.01	1.28	1.28	1.43	1.46
Dia- meter in cm	3.535 3.535	3.596	3.552	3.532	4.743	4.432
Thick- ness in cm	0.201	0.199	0.199	0.197	0.163	0.221 0.1169
Time in Hrs.	11	רט רט	20	20 20	15	4 4 2
Actual Temp Oc	1380 1380	1280 1280	1260	1300	11.25	1100
Pressure used psi	5 000			8,000	Providence and a supplementary of the first state of the supplementary o	000
Sample No.	нн	V	ΔΙ	VII	Τχ	XIII
Batch No.		† <b>4</b>			B#	Q

+First calcinca at 1000°C for 4 hours. \*First forsterized at 1355°C for 20 hours.

 $<sup>\</sup>phi_{\mathrm{Later}}$  on this thickness was brought down to 0.0724 cm.

TABLE 11
Thermal History and Composition of Forsterite Samples Used for X-ray Diffraction

Sample	No.	Composition	Temp. OC	Time Hrs.	Pressure applied psi
Fl		В	1355	20	
F <sub>2</sub>		В	1100	$4\frac{1}{2}$	
F <sub>3</sub>		В	1200	12	
F <sub>4</sub>		В	1200	12	
$G_1$		$\mathtt{C}_\mathtt{l}$	1100	4 1/2	5000
G <sub>2</sub>		$C_2$	it is a second of the second o	11	
G <sub>3</sub>	•	c <sub>3</sub>	#	e e e e e e e e e e e e e e e e e e e	
G <sub>4</sub>		C <sub>4</sub>	Tall of a	11 (1) (1) (1) (1) (1) (1) (1) (1) (1) (	
H <sub>1</sub>		${\tt C}_{\tt l}$	1200	5	
H <sub>2</sub>		C <sub>2</sub>	<b>H</b>	11	
H <sub>3</sub>		03		11	
H <sub>4</sub>		C <sub>4</sub>	11	11 11 11 11 11 11 11 11 11 11 11 11 11	

TABLE 12

	Stoichiometric Talc-	Average percent calculated density	E SECTION OF THE CONTRACT OF THE SECTION OF TH	73	91	09	81
	mples of Usea	Average percent theoretical density	CONTRACTOR AND STATEMENT OF THE PROPERTY OF TH	9/	94	64	8 5
12	terite Aáaitiv ements	Average Fired density, gms/cc	)	2.44	3.02	2.05	2.73
TABLE 12	1 History of Fors Composition with Electrical Measur	Average diameter, cm	0	444 2000 4000 4000 4000 4000	4.035 4.034 4.025 4.046	4.531 4.540 4.544 4.543	4.097 4.097 4.167 4.124
		Average thick- ness, cm	)	0.052 0.085 0.107 0.597	0.079 0.078 0.111 0.544	0.043 0.104 0.111 0.248	0.070 0.092 0.062 0.402
	and Therma Magnesite for	Time hrs	4	W= = =	₩= = = =	€ = = =	V===
	n Lata	Temp.		1150	1200	1150	1200
	Densification Lata	Sample No.	7	H0W4	H004	H0W4	H 0 10 4
	Densi	Batch No.	<u> </u>			E	C)

. . . Contc.

Table 12 (... Conta.)

6	85	85	41	5.0
	06	91	43	62
Angles (in of Law Andle Angels (in Angels Angels (in Angels A	2.89	2.90	1.36	1.98
9	4.037 4.026 4.010 4.030	3.985 3.962 3.979 3.982	4.873 4.881 4.879 4.894	4.617 4.630 4.625 4.629
	0.107 0.105 0.115 0.405	0.057 0.061 0.054 0.477	0.047 0.057 0.044 0.290	0.053 0.085 0.093 0.394
7	rv = = =	ν= = =	W= = =	ΓV = = =
	1150	1200	1150	1260
2	10N4	H0W4	H0N4	H004
man description of the second		5		7

Pressure applied = 5,000 psi.

TABLE 13

Donsification Data and Thermal History of Forsterite Samples of Stoichiometric Talc-Magnesite Composition with BaCO3 Additive and also of Stoichiometric MgCO3-SiO2 Used for Electrical Measurements

Average Average percent calcu- water lated absorp-density tion	86 0 98	87 0.14	67 0.20	87 0.50	88 1.07
Average percent theore- tical density	91	93	95	92	89
Fired density gms/cc	2.91	2.98	2.96	2.09	2.85
Average Liameter cm	4.0938	4.0854	4.0868	4.0724	3.9172 3.9024
Average thi ckness cm	0.5152	0.5464	0.5168	0.4812 0.5058	0.5250 0.5070 0.5078
Time hrs	10	10	10 10	10	10 10 10
Temp.	1160	1180	1200 1200	1220	1400 1400
Sample No.	H	22	4D	9	PM1 PM2 PW3
Batch No.			C 2		A

Pressure applica = 5,000 psi

TABLE 14

ASTM X-ray Lata for Forsterite, Periclase, Protoenstatite, Protoenstatite (high form) and Clinoenstatite

Forst	erite	Pericla	ase	Protoen	statite	tite (		Clinoer tite	nsta-
dÅ	I/I <sub>o</sub>	dÅ	I/I <sub>o</sub>	άÅ	I/I <sub>o</sub>	form dA	I/I <sub>o</sub>	άÅ	I/I <sub>o</sub>
5.110	26	2.106	100	3.16	100	3.240	20	4.4130	12
3.880	69	1.489	52	2.97	20	3.170	100	3.2867	50
3.730	25	1.216	12	2.90	40	2.908	40	3.1743	60
3.487	21	0.9419	17	2.87	20	2.726	20	2.9795	95
3.000	17	0.8600	15	2.72	20	2.551	30	1.8783	100
2.768	53			2.54	40	2.305	20	2.5418	35
2.513	73			2.29	20	1.975	20	2.5238	35
2.458	100			1.96	60	1.968	20	2.4594	60
2.268	59			1.71	20	1.716	13	2.4358	20
2.250	33			1.63	40	1.642	20	2.3793	16
2.161	15			1.49	60	1.499	15	2.2186	20
1.748	60			1.37	20	1.495	15	2.2080	20
1.670	13			1.31	40			2.1399	12
1.636	12			1.26	20			2.1190	45
1.618	15							2.1150	45
1.497	27							1.7874	12
1.479	30							1.7648	12
1.396	12							1.7626	12
1.351	17							1.7333	12

TABLE 15  $\text{ASTM X-ray Data for Enstatite, $\alpha$-Quartz, $\beta$-Quartz, $\alpha$-Cristobalite }$ 

Enstat	ite	c-Quar	tz	β-Quar	tz	α-Cris	toba-	β-Cris	toba-
åÅ	I/I <sub>o</sub>	dΑ	I/I <sub>o</sub>	aA	I/I <sub>o</sub>	lite dA	I/I <sub>o</sub>	lite dA	I/I <sub>o</sub>
4.410	14	4.260	35	4.34	20	4.04	100	4.15	100
3.303	35	3.343	100	3.40	100	3.138	12	2.53	80
3.167	100	2.458	12			2.845	14	2.07	30
2.941	45	2.282	12			2.489	18	1.641	60
2.872	85	1.817	17					1.460	50
2.825	25	1.541	15					1.380	20
2.706	25	1.375	11					1.266	30
2.534	45							1.210	30
2.494	50							1.131	20
2.471	30								
2.114	25								
2.096	20								
2.058	14								
1.984	14					and the second of the second o			
1.958	25								
1.603	20								
1.520	14								
1.485	35								
1.470	20								

TABLE 16

ASTM X-ray Data for Low Cordierite, Magnesium Aluminate, Barium Silicate, Barium Aluminium Silicate and Barium Magnesium Silicate

	-									
Low Cordie	rite	Magne: Alumi		Bariur Silica		Barium	n ,	Barium Silica		siur
a A	I/I <sub>o</sub>	a 8	I/I <sub>o</sub>	d A	I/I <sub>o</sub>	Silica d A	I/I <sub>o</sub>	d A	I/I <sub>o</sub>	
8.52	95	2.43	90	6.95	20	6.39	40	4.04	20	
8.45	100	2.01	70	3.746	100	4.57	20	3.75	30	
4.91	30	1.43	100	3.669	60	3.77	30	3.54	100	
4.67	14			3.299	50	3.44	60	3.34	50	
4.09	50			3.249	55	3.33	70	. 3.28	40	
3.381	50			3.123	30	3.24	70	3.19	20	
3.369	40			3.120	30	3.00	70	3.836	20	
3.149	25			2.794	16	2.901	40	3.711	20	
3.132	55			2.780	40	2.758	50	3.655	40	
3.039	65			2.756	35	2.574	100	3.601	30	
3.035	65			2.343	20	2.406	30	2.514	40	
3.012	55			2.267	45	2.316	30	2.364	30	
2.650	20			2.221	20	2.263	20	2.264	20	
2.644	20			2.199	16	2.167	100	2.197	30	
2.637	12			2.132	90	1.994	20	2.157	30	
2.334	12			2.080	16	1.946	20	2.114	30	
2.107	12			2.076	18	1.801	50	1,928	20	
2.102	12			1.975	12	1.625	20	1.826	40	
				1.970	18	1.576	20	1.607	30	
				1.911	14	1.455	50	1.586	30	
				1.874	12	1.428	60			

TABLE 17

ASTM X-ray Data of Compounds Used for Identification of Unknown Phases

and the second s				
Name	Formula	a A	Intensity	ļ.
Mullite syn*	3A1 <sub>2</sub> U <sub>3</sub> .28i0 <sub>2</sub>	3.39-3.43-2.21	100-95-60	ı
Barium magnesium silicate	BazMgSi <sub>2</sub> 08	2.81-2.93-4.05	100-95-70	
Barium magnesium silicate	Ba <sub>2</sub> MgSi <sub>2</sub> 07	3.17-2.92-1.94	100-55-45	
Barium magnesium silicon oxiae	BaMgSiO4	3.15-2.63-4.57	100-45-40	
Barium silicate	Ba281308	3.79-3.33-5.28	100-87-76	
Barium silicate	Ba5 Si 8 0 21	3.26-3.74-5.80	100-30-80	
Barium silicate	Bazsi5013	3.85-3.78-5.25	100-80-80	
. silica	Basi <sub>2</sub> 05	5.97-5.09-3.34	100-75-70	
Alpha Barium silicate (high temp.)	α-BaSi <sub>2</sub> 05	4.05-2.22-3.17	100-80-75	
Beta Barium silicate (low temp.)	6-Basi <sub>2</sub> 05	3.09-4.00-3.32	100-95-95	
	Basi <sub>4</sub> 0 <sub>9</sub>	3.49-6.96-2.31	1008080	
	Bao.48i0 <sub>2</sub>	3.54-2.91-2.05	100-65-45	
Barium magnesium aluminium silicate	BaMc2.413	7.18-3.25-2.93	100-100-00	
	(SigAl3030)			
Barium aluminate	Ba3A1206	2.91-4.12-2.06	100-35-25	
	BaAl <sub>12</sub> 0 <sub>19</sub>	2.51-2.79-2.70	100-85-82	6
	$BaAl_2O_A$	3.17-4.56-2.62	100-80-80	7

Table 17 (... Contá.)

	AND THE STATE OF T	ACH ETHIGH THE CANTENAN MATERIAL ABBRERRAL METHORSHIP METHORSHIP LANGUAGE CANTENAN C	The state of the s
Name	Formula	a A	Intensity
Barium aluminosilicate		2.48-3.53-3.33	100-70-60
Barium aluminium oxiae	Ba3A1206	2.92-4.15-2.38	100-4025
Barium aluminium silicate	$Ba_3A1_6Si_2U_16$	3.07-3.09-3.52	100-65-50
" /Barium feldsper q syn	BaAl <sub>2</sub> Si <sub>2</sub> 08	3.29-2.97-3.99	100-100-70
" /Paracelsian	BaA1281208	4.00-5.30-2.99	100-70-50
" /Celsian syn	BaAl <sub>2</sub> Si <sub>2</sub> 08	3.36-3.48-2.59	100-65-50
	BaAl <sub>2</sub> Si <sub>2</sub> 08	7.79-1.95-2.97	100-65-50
Magnesium aluminium oxide/spinel syn	$MgAl_2O_4$	2.44-2.02-1.43	100-58-58
Magnesium aluminium silicate/High cordierite	Mg2A145i5018	8.48-3.05-5.14	100-85-65
" /Cordierite	Mg2Al4Si5U18	3.13-8.54-8.45	100-80-80
Gamma aluminium oxide/ $\gamma$ alumino syn	Y-A1203	1.98-1.40-2.39	100-100-80
Spare to describe the sides are reduced to the second transformation or the second spare to the second spa	THE PROPERTY OF THE PROPERTY O		

syn: synthetic.

X-ray Diffractogram of Stoichiometric Forsterite Composition With Talc and Magnesite Sintered at 1350°C for 10 hours (E1) and at 1300°C for 10 hours (E2) respectively

(A) List of six higher intensity lines of forsterite phase. (B) List of lines of intensity  $I/I_0$  higher than 10 for phases other than forsterite

(A)

AND THE PROPERTY AND TH	E <sub>1</sub>			E <sub>2</sub>	
d A	I/I <sub>0</sub>	Phase	d A	I/I <sub>o</sub>	Phase
2.47	100	F	2.46	100	F
2.52	90	F	2.51	90	F
2.77	70	F,	1.74	75	F
1.75	69	F	2.77	61	F
2.27	60	$\mathbf{F}$	2.27	55	F
3.90	51	F	3.88 1.50	49 49	F F

$E_{7}$			E <sub>2</sub>	
I/I <sub>o</sub>	Phase	d A	I/I <sub>o</sub>	Phase
16	βC	4.08	33	αC
19	P/PH/E	3.17	36	P/PH/E
12	P/PH/E	2.90	11	P/PH/E
13	PH/P/E			
	1/I <sub>o</sub> 16  19  12	1/I <sub>0</sub> Phase  16 βC  19 P/PH/E  12 P/PH/E	1/I <sub>o</sub> Phase d A  16 βC 4.08  19 P/PH/E 3.17  12 P/PH/E 2.90	1/I <sub>o</sub> Phase d A 1/I <sub>o</sub> 16 βC 4.08 33  19 P/PH/E 3.17 36  12 P/PH/E 2.90 11

TABLE 19

X-ray Diffractogram of Stoichiometric Forsterite Composition with Talc and Magnesite Sintered at  $1250^{\circ}\text{C}$  for 10 hours (E3) and  $1200^{\circ}\text{C}$  for 10 hours (E4) respectively.

(A) List of six higher intensity lines of forsterite phase.
(B) List of lines of intensity I/I<sub>0</sub> higher than 10 for phases other than forsterite

(A)

			/		
	errener ye err Uderwee Armiterere (errener) - de miner	3	Television and Careful Television (Television)	E <sub>4</sub>	
d A	I/I <sub>o</sub>	Phase	a A	I/I <sub>o</sub>	Phase
2.46	100	F	2.45	100	F
2.52	84	F	2.51	89	F
2.76	67	F	2.24	69	F
1.75	64	$\mathbf{F}$	1.74	69	F
3.88	54	${f F}$	2.76	63	F
2.28	53	$\mathbf{F}^{(1)}$	2.26	51	F

	COMMON PROPERTY DESCRIPTION OF	13			E <sub>4</sub>	
a A		I/I <sub>o</sub>	Phase	à A	I/I <sub>o</sub>	Phase
3.18		34	P/PH/E	3.17	24	P/PH/E
2.90		29	P/PH/E	2.89	30	P/PH/E

X-ray Diffraction of Stoichiometric Forsterite Composition with  $Mg(OH)_2$  and  $SiO_2$  sintered at 1355 C for 10 Hours and 1100 C for  $4\frac{1}{2}$  hours Respectively.

(A) List of six higher intensity lines of forsterite phase. (B) List of lines of intensity  $I/I_0$  higher than 10 for phases other than forsterite.

(A)

pagengalescuring ethic: Tauachtainean infrinciación ethic	${\mathtt F}_{\mathtt l}$			F <sub>4</sub>	erienverside Melmerinearen ganzaratzen albaniaren (hara
a A	I/I <sub>o</sub>	Phase	d A	I/I <sub>o</sub>	Phase
2.46	100	F	2.46	100	F
2.51	82	F	3.34	90	F
2.77	77	$\mathbf{F}$	2.51	80	F
1.75	70	F	2.77	68	<b>F</b>
3.90	66	$\mathbf{F}^{-1}$	1.75	63	F
2.27	50	$\mathbf{F}$	3.89	57	F
2.25	50	F			

METERS OF THE SHOP SHOP STREET AND SHOP SHOP SHOP SHOP SHOP SHOP SHOP SHOP	Fl		Annual Control of the	F <sub>4</sub>	
a A	I/I <sub>o</sub>	Phase	d A	I/I <sub>o</sub>	Phase
	P Halfurfu BB pas Affilia Ashinu Make ya Karanga Karanga Karanga Karanga Karanga Karanga Karanga Karanga Karang		4.29	26	αQ
			3.34	90	αQ
			3.17	20	P/PH/E
			3.08	11	TC
			2.72	29	PH
			2.51	80	βC/F
			2.11	52	M
			1.94	20	F/P/PH
			1.49	51	M/F/P
			1 <i>.3</i> 8	12	MA

X-ray Diffraction of Stoichiometric Forsterite Composition with Mg(OH)<sub>2</sub> and SiO<sub>2</sub> both Sintered at 1200°C for 12 hours.

(A) List of six higher intensity lines of forsterite phase. (B) List of lines of intensity  $I/I_0$  higher than 10 for phases other than forsterite.

Array Prints and Print	F <sub>2</sub>		A)	Fz	
a A	I/I <sub>o</sub>	Phase	d A	I/I <sub>o</sub>	Phase
2.48	100	F	2.47	100	F
2.53	63	F	2.53	76	F
1.74	61	$\mathbb{F}'$	1.75	64	${f F}$
2.26	58	F	2.78	59	F
2.79	55	F'	3.92	58	F
3.93	50	$\mathbb{F}$	2.27	54	F

F <sub>2</sub>			F <sub>3</sub>	
a A I/I <sub>o</sub> I	Phase	d A	I/I <sub>o</sub>	Phase
3.38 22 0	ιQ	4.31	22	αQ
3.20 21 I	P/PH/E	3.37	83	$\alpha Q$
3.02 19 I	1C	3.20	26	P/PH/E
2.48 100 F	· /M	3.01	27	LC/F
1.50 40 N	1/F/P	2.90	11	P/PH/E
		2.53	76	βC/F
		1.64	20	βC/F
		1.52	12	P/F
		1.48	42	M/F

X-ray diffraction of Stoichiometric Forsterite Composition of Talc, Magnesite With Additives, both Sintered at  $1100^{\circ}$ C for  $4\frac{1}{2}$  hours

(A) List of six higher intensity lines of forsterite phase. (B) List of lines of intensity  $I/I_{\rm o}$  higher than 10 for phases other than forsterite.

(A)

meaning of the second second second	G1	awang tinaka ngang sakununka Pri pinlanngga Jawahin nyain nga Ara s	AN COMPANY OF THE PROPERTY OF	G	and the state of t
a A	I/I <sub>o</sub>	Phase	d Å	I/I <sub>o</sub>	Phase
2.46	100	F,	2.46	100	F
2.51	93	$\mathbb{F}$	2.78	81	F
2.77	68	F	3.90	71	F
1.75	61	F	1.75	69	F
3.88	59	F	2.27	54	P
2.25	49	F'	3.90	71	F

Section and a section of the section	$G_{l}$	CONTROL OF THE PROPERTY OF THE		<sup>G</sup> 2	
a A	I/I <sub>o</sub>	Phase	d A	I/I <sub>o</sub>	Phase
4.31	12	αQ	4.33	16	αQ
3.30	13	$\alpha$ Q	3.64	21	BS
3.17	45	P/PH/E	3 <b>.</b> 35	42	$\alpha Q$
3.05	11	LC	3.30	32	BAS
2.94	17	P/PH	3.18	23	P/PH/E
2.88	34	PH/P/E	3.07	20	ГС
2.73	35	PH	2.91	29	P/PH/E
2.39	11	MA	2.73	32	PH
1.49	36	M/F/P	2.60	32	PH
			2.51	95	F/P
			1.62	26	F/P
			1.48	41	F/P
			1.32	16	F/P

X-ray Diffraction of Stoichiometric Forsterite Composition of Talc, hagnesite with Additives, both Sintered at  $1100^{\circ}$ C for  $4\frac{1}{2}$  hrs.

- (A) List of six higher intensity lines of forsterite phase.
- (B) List of lines of intensity  $I/I_{\rm O}$  higher than 10 for phases other than forsterite.

(A)

MATERIA SANCTINE AND THE PROPERTY AND THE SANCTINE AND TH	AND THE PROPERTY AND LONG TO SECURITY AND	and distance and their way desirings. The desirence indicates the annual state of the state of t	ATTACAPHATICORNAL A MERITANIANIA (BANGCELANICAMA) (S. 1800) TACAPHATINGA (S. 1800)	G <sub>4</sub>	
d Å	I/I <sub>o</sub>	Phase	a A	I/I <sub>o</sub>	Phase
2.45	100	F	2.45	100	F
2.51	93	${f F}$	2.51	83	F
2.77	79	F	1.75	63	F
3.88	73	${f F}$	2.76	60	F
1.75	69	$\mathbf{F}$	3.88	55	$\mathbf{F}$
3.48	55	F	2.26	51	F

-		G <sub>3</sub>	e Palar de Nagari, y no successo de Arte dos Servicios de Consecuencia de Consecuencia de Consecuencia de Cons		<sup>3</sup> 4	
d A	ORICLASSI SAMMA GALLISANOSTI JARO PLAN	I/I <sub>o</sub>	Phase	å Å	I/I <sub>o</sub>	Phase
4.31	T Marie Transport Communities And Annual Communities (Communities Communities Communities Communities Communit	19	αQ	3.17	37	P/PH/E
3.64		23	BA	2.88	33	p/PH/E
3.56		30	BMS	1.48	41	M/F
3.36		58	$\alpha$ Q			
3.28		29	BMS			
3.18		16	P/PH/E			
2.91		23	P/PH/E			
2.72		33	PH			
2.59		28	PH			

X-ray Diffraction of Stoichiometric Forsterite Composition of Talc, Magnesite with Additives, both Sintered at 1200°C for 5 hours.

(A) List of six higher intensity lines of forsterite phase. (B) List of lines of intensity  $I/I_0$  higher than 10 for phases other than forsterite.

(A)

and any house, we are with the market of		er ville die Minister von de deutsche Professioner andere deutsche deutsche des des deutsche des	The surviving of the contract of the surviving of the contract	$\mathrm{H}_2$	
a A	I/I <sub>o</sub>	Phase	αÅ	I/I <sub>o</sub>	Phase
2.46	100	F	2.46	100	P
2.51	78	F	2.51	74	F
1.75	58	F	2.76	64	F
2.77	55	$\mathbf{F}$	2.25	58	F
3.88	54	F	1.75	52	F
2.25	48	F	3.88	46	F

matter vir traventine diffiliacement i monecule.	II		ggiograficament products, septem of all products of the products absent	H <sub>2</sub>	
d A	I/I <sub>o</sub>	Phase	d Å	I/I <sub>o</sub>	Phase
3.18	37	P/PH/E	3.35	36	αŲ
2.88	32	P/PH/E	3.27	38	BMS
2.46	100	F/M	3.17	33	P/PH/E
			2.91	34	P/PH/E
			2.58	23	PH
			2.46	100	F/M
			1.94	11	P/F
			1.49	35	M/F/P

TABLE 25

X-ray Liffraction of Stoichiometric Forsterite Composition of Talc, Lagnesite with Additives, both Sintered at 1200 C for 5 hours

(A) List of six higher intensity lines of forsterite phase. (2) List of lines of intensity  $I/I_{\rm O}$  higher than 10 for phases other than forsterite.

(A)

	H <sub>3</sub>	Charles and the company of the Continue of the	The same of the sa	angelen 1986 - Higgelië kollender i Hijkoli Mang ; a ve en mandelen	H <sub>4</sub>	
à À	I/I <sub>o</sub>	Phase	interpretation		I/I <sub>o</sub>	Phase
2.45	100	F		2.47	100	F
2.51	93	F		2.52	73	$\mathbf{F}^{i}$
1.74	64	F		2.79	53	F
2.77	61	F,		1.75	53	F
2.26	56	F		2.25	49	F
3.87	51	F		1.48	48	F

And the second s	E <sub>3</sub>			H <sub>4</sub>	
á A	I/I <sub>o</sub>	Phase	a A	I/I <sub>o</sub>	Phase
3.33	11	αQ	3.18	44	P/PH/E
3.19	28	P/PH/E	3.02	27	ŤC
5.06	16	ΤC	2.89	35	P/PH/E
2.88	65	P/PH/E	2.47	100	F/M
2.45	100	F/M	2.13	12	M
2.10	50	M	1.95	11	P/F
2.04	12	MA			
1.94	12	P/F			
1.49	47	M/F/P			

TABLE 26
Unidentified X-ray Liffraction Lines in Forsterite Compositions

Sample	á Å	I/I <sub>o</sub>	Sample	á A	I/I <sub>o</sub>
E	3.65	23		6.56	16
$\mathbf{F}_{1}$	5.45	16	0	5.65	10
F <sub>3</sub>	1.55	10	<sup>G</sup> 2	4.67	10
				1.46	11
F <sub>4</sub>	1.38	12		6.60	17
Gl	1.66	11	G <sub>3</sub>	4.67	12
				1.50	46

TABLE 27

Measurement of K and Q of Electroded Forsterite Samples Using Two Connecting Leads on Each Face

Frequency Kc/s	I	Ö	III	Canada administration (Canada	I	I Q	an charter and strangeness as a large	7	X	TA	, ,
	7 86	7	77.77	4.0,	E L L	427	92.9	202	5 80	0 L L	,
)	•	1	- 1	) i	•	-	•		0.0	7	
200	8.39	54	7.64	6.5	7.28	1224	92.9	2863	6.92	162	
400	7.71	30	7.53	ω	6.94	91	6.53	159	99.9	215	
308	7.76	20	7.65	46	7.18	559	6.71	515	6.74	350	
1500	7.69	193	7.65	149	08.9	88	62.9	874	6.54	1633	
2600	7.73	118	7.70	169	7.27	284	6.75	959	08.9	939	
2009					7.06	80	6.54	557	6.62	276	
11500	7.72	133	7.76	254	7.35	46	92.9	685	6.91	820	
den sedigin masana decimano so ken regiona estados especiales	transport that the state of the state	general description and the second description of	o detapora desse filos esperançamentes es pelos	Andread - 1800-180, 100 personal and the second	A STATE AND ADMINISTRATION OF THE PROPERTY OF	AN ANTERIOR WITCHWARDSHIPS IN THE RESERVE	enderstatement plants a teacherstatement en	voets was an exemplanation and the second	Annual Minister Minister Security (1997)	Мациянский и от технология представления в представления в представления в представления в представления в пред	_

TABLE 28

Measurement of K and Q of Unshielded and Electroded Forsterite Sample Using Different Number of Leads and Different Lead Length

MORROW HOLLOW VIEW Charles Control Con	AND THE PERSON AND THE PERSON IN THE PERSON AND THE	The second of the second secon				
Frequency Kc/s		d on each ead length	TOTAL CONTRACT OF THE PARTY OF		siae bu	on each t using a; Lead 5 cm
	A	Q	K	ୠ	K	Q
5000	7.88	50	7.28	922	8.13	182
6000	7.64	59	6.88	259	8.05	112
7000	7.83	64	7.23	260	8.17	128
8000	7.87	70	7.37	294	8.32	119
9000	7.82	75	7.26	324	8.23	88
10000	7.79	71	7.14	257	8.14	100
11000	7.90	82	7.22	237	8.19	81
12000	8.05	72	7.29	283	8.35	88

TABLE 29

Measurement of K and Q of Unshielded and Electroded Forsterite
-Sample Using Different Lead Lengths

Frequency	द्रा		X	AND MAKE THE ALMSO NAME OF BRANCHES BAREFUL.		
Kc/s	K.	lead Q	6'' K	lead Q	12 K	" lead ପୃ
2500	4.62	172	4.53	376	4.65	270
3000	4.49	220	4.56	313	4.63	288
4000	4.55	231	4.60	286	4.80	279
<sup>¥</sup> 4200	4.62	206	4.65	285	4.83	235
4200	4.58	224	4.63	282	4.81	273
**4700	4.53	275	4.59	272	4.75	282
5000	4.53	275	4.57	272	4.77	271
5 500					4.78	226
5700	4.58	222	4.62	291		
4700	4.55	242	4.56	247	4.78	271
5000	4.54	492	4.51	273	4.74	336
5700	4.44	252	4.50	334	4.74	298
7000	4.44	275	4.58	392	4.86	254
9000	4.56	258	4.64	261	5.00	247
*10000	4.49	229	4.63	212	5.05	177
10000	4.52	223	4.65	214	5.06	167
11000					4.55	144
11200			4.74	222		
11400	4.61	199				

<sup>\*</sup> Frequency switch changed

<sup>\*\*</sup>Frequency overlap between higher and lower range.

TABLE 30

Measurement of R and Q of Unguarded, Electroded and Wired Forsterite Sample

XIV		Frequency
		Kc/s
87	4.85	55
228	4.88	80
316	4.89	190
361	4.85	350
345	4.87	500
275	4.88	600
342	4.85	800
417	4.89	1000
340	4.86	1300
386	4.85	1700
418	4.87	3000
287	4.89	4300
235	4.88	7000
216	4.94	8300

TABLE 31

Measurement of K and Q of Forsterite Samples, Sintered at 1150°C and 1200°C for 5 hours, under Lifferent baking Condition

	prince guity made incommended to the prints requirements	To the state of th		Anna de descripción d	TV.	ter 90	min.	bakin	ig at	150°C					
Frequency	Sample (	6, /11	C <sub>1</sub> /1150/5	$c_2/11$	150/5	$/1150/5$ $c_2/1200/5$	5/00	$c_{3}/11$	$c_3/1150/_5$	$c_3/1200/5$	5/00/5	C <sub>4</sub> /11	$c_4/1150/5$	$c_4/1$	C4/1200/5
	• 0 N	114	()	K	'n	X	Ö	K	Ö	K	Ĉ	X	(ئ	K	6)
March Breit Merchant of their state of the S	The state of the s	5.0	464	4.5	432	0.9	356	6.3	280	9.9	254	9	162	4.2	227
	1 2	5 5	325	4.7	347	6.2	347	6.2	267	6.7	551	U. 51	170	3.8	189
70 kc/s	2	5.2	394	4.6	423	6.1	336	6.2	329	6.5	620	5.3	188	3.2	186
	4	6.9	299	5.4	278	8.1	72	7.9	198	0.6	391	¢., 6	42	4.9	129
	Н	5 5	456	4.5	338	0.9	411	6.3	730	9.9	962	ે.	212	4.1	196
	2	5.1	235	7.7	355	6.1	453	6.2	708	6.7	726	9.	244	4.2	181
1.1 Mc/s	50	5.2	263	4.7	351	0.9	399	6.3	493	6.5	578	5.3	253	3.6	195
	. 4	6.3	474	5.3	255	8.2	217	7.6	528	9.5	579	4.5	111	5.0	207
	Н	5.2	163	9.4	189	6.2	227	6.3	386	6.8	246	J. C	209	4.1	175
7 7 7 7	2	5,3	39	4.7	335	6.2	248	6.3	299	6.9	204	5.0	219	4.2	157
LL MC/ B	$\omega$	5.2	108	4.6	358	6.2	185	6.3	493	9	183	5.3	204	4.1	226
	4	7.1	462	5.5	373	7.7	314		470	50	545		141	5.2	295
		The second second	specimental appropriate of	niye. A spiring Kulingski tibika gasa		And the same of the same	enenenenenenenenenenen	To the second second				delica attendante delicationi	en den - Arcen Estados des		Proposition and address and

... Conta.

TABLE 31

Measurement of K and Q of Forsterite Samples, Sintered at 1150°C and 1200°C for 5 hours, under

Annual designation of the second of the seco		Control of the contro		econtacionelles y activistes sinnecen		tor 90	min.	bakin	ig at	150°C			1/2		
Frequency	No.	C <sub>1</sub> /1150/5	50/5	C <sub>2</sub> /11	50	$\frac{7}{6}$ $\frac{6}{6}$ $\frac{1200}{6}$	0	$\frac{c_3/1150/5}{K} = \frac{c_3/1200/5}{K}$	20/5	C <sub>3</sub> / L <sup>2</sup>	3,007	C4/1150/5 K Q	50/2		C4/1200/5 K Q
ender der Seine Seine Seine Seine Seine Seine Seine	riden, vid kandesvija Odjana Bilanja i di melete saki	TO AND COMPLETE STATE OF SHALL IN	encateran Brankschler - "Y-	AND BEEF FEBRUARISHESS OF THE PARTY.		e alasta de fice de la maga ampaian.	And the second s		d Berthamen and The State His Tolk	And the second control of the second	4 94 Tokanajiran 94	Statement (december 1977 - 1984)	No. of Contract Contracts		pulpy Printerior Ender No. 16: 18
	Н	5.0	464	4.5	432	0.9	356	6.3	280	9.9	254	2.9	162	4.2	227
) }	2	5.3	325	4.7	347	6.2	347	6.2	267	6.7	551	5.5	170	3.8	189
8/0X O).	<b>1</b>	5.2	394	9.4	423	6.1	336	6.2	329	6.5	620	5.3	188	3.2	186
	4	6.9	299	5.4	278	8.7	72	7.9	198	0.6	391	9.7	43	4.9	129
	Н	5,0	456	4.5	338	0.9	411	6.3	730	9.9	962	٥. ن	212	4.1	156
) (3F	2	5.1	235	7.5	355	6.1	453	6.2	708	6.7	726	9.0	244	4.2	181
L.L MC/B	8	5.2	263	4.7	351	0.9	399	6.3	493	6.5	578	5.3	233	3.6	195
	4	6,3	474	5.3	255	8.2	217	7.6	528	9.5	579	4.5	111	2.0	201
	. H	5.2	163	4.6	189	2.9	227	6.3	396	8.9	246	J. C	209	4.1	175
ט/טאַ רר	2	5,3	39	4.7	335	6.2	248	6.3	299	6.9	204	3.5	219	4.2	197
7 LIC 1	20	5.2	108	4.6	338	6.2	185	6.3	493	6.8	183	5.3	204	4.1	226
	4	7. J	462	5.2	373	7.7	314	ာ အ	470	0.0	549	9.4	141	5.5	295

... Conta.

hable 31 ( Contá.)	(Cont	ja.,)	A	化二氢甲基甲基甲基甲基甲甲基甲二氢甲甲二氢甲甲甲甲甲甲甲甲甲甲甲甲甲甲甲甲甲甲甲		Tter ]	150 m	inutes	s baki.	ng at	15,300		10 mg	CHARACTER CAN A SECURE OF THE SECURE CAN A S	pay by and an in the
Tredu Phey		0,/1150/5	1	$C_{2}/115$	3/15	$c_2/1.20$	50/5	$\frac{c_3}{1}$	150/5	$\frac{c_{3}/12}{}$	00/5	$c_4/1$	50/5	$c_{4}/1200/5$	30/5
) ;; ; ; ;	No		Ô	K	()	X	(1)	K	K Q K Q K G K	K	(2)	K	3	K	Ö
TOTAL ACTION AND THE PROPERTY OF STREET, AND STREET, A	No. resentiva entrata in the two seathfully of the	() V	436	4.3	809	5	409	6.4	412	6.4	943	2.7	319	3,8	292
	-l C	. 6.	424	4.1	554	5.6	259	6.4	887	6.4	892	5.5	250	3.6	254
70 Kc/s	J K	4,0	393	4.0	524	5,8	430	6.4	419	6.2	606	2.9	210	5.7	294
-  -	) 4	6.0	181	4.4	381	5.9	297	6.8	124	6.7	757	3.7	94	4.2	24
		ή. Θ.	447	4.5	255	5.8	386	6.3	156	6.4	1048	2.7	273	S	188
	٦ ،	4.9	381	4.1	405	5.6	727	6.2	484	6.4	1000	3.1	295	3.8	177
l, l Mc/s	J 17	6.4	304	4.1	259	5.8	515	6.4	889	6.2	921	2.8	15¢	3,8	208
· 	7 7	4.8	349	4.2	292	6.1	368	7.4	1769	9.9	786	3.5	135	5.4	700
	-	5,0	134	4.4	09	5,0	234	6.4	437	9.9	254	2.7	218	5.5	152
	1 N	5.0	110	4.2	538	5.7	27.1	6.3	99	6.7	254	5.2	245	7.0	162
11 Mc/s	<b>1</b>	4.9	89	4.1	91	o°9	193	6.5	460	9.9	139	2.9	139	3.8	210
	4	4.7	537	4.3	181	7.5	685	7.5	1600	6.5	875	5.5	242	5.4	282
en e	i general de destaca de de composito de la composito de c		r. na menonamunamunamunder.	popular and debuggion a Transmission in the constitution	A control and a control of the contr	New Company of the Co	Mode of Wilderspendingers a 2 Total	C. MIC Association because	In Advantage of Mark of Africa Solding	riburilla in McPalaporabo" (Gene in Lebo	Annual time with the subspection below		s. In third Agency transfer, and	An east observation to the execute	Bookstellinester it sjygovy tikatile

TABLE 52

Measurement of K and Q of Electroded Forsterite Samples
Using Parallel Plate Set up

Frequency	I			V	VI	I
Kc/s	I	Q	K	Q	K	Q
105	5.77	227	6.70	57	5.89	82
2600	5.97	200	6.77	149	5.91	83
11500	5.60	85	6.53	71	5.79	33

TABLE 33

Measurement of K and Q of Electroded Forsterite Samples
Using Parallel Plate Setup with Sharp and Flat Contacts
at Either Ends

Acceleration of the consequence	COM. ALTONO ME STREET, AND			and repaired, given a substitution of the continues of th		
Frequency	I		VI	<u> </u>	V	£
Kc/s	K	Q	K	Q	K	Q
engania dell'impercora difficione i il respecti percora del «Tembrio» especiali	or the confident describerations where consider more	PODE : THE STATE OF THE STATE O	nger (pole-roefe primer) andergous per minosopis, est	HATTERS OF MANY AND ADMINISTRATION OF THE		
105	6.62	424	6.54	175	7.68	33
2600	6.81	262	6.93	200	7.58	69
11500	6.77	91	6.64	56	7.67	157

<sup>\*</sup>For this sample same assembly was used but with wire scratched at a portion.

TABLE 34

Measurement of K and Q of Air by the Unguarded Capacitance Cell

Air gap cm	55 K	Kc/s Q	80 K	kc/s Q	
0.025	1.28	2832	1.62	889	
0.050	1.21	2161	2.02	1752	
0.075	1.28	758	2.51	2517	
0.100	1.33	985	3.00	709	
0.125	1.38	818	3.48	2032	
0.150	1.48	625	3.96	339	
0.175	1.55	1975	4.43	1849	
0.200	1.63	1213	4.91	519	
0.250	1.63	2916	5.89	324	
0 <b>.</b> 300	1.82	2720	6.84	989	
0.350	1.95	2495	7.78	470	
0.400	2.16	1607	8.74	462	
ŭ <b>.</b> 500	2.26	2019	10.68	452	

TABLE 35 Measurement of  $\triangle$  C and Q of Unguarded Forsterite Samples Using Capacitance Gell.

Company of the Compan	an commence of the same of	ethinese partimeter (in ethinology) i partimeter (in ethinology)	electronic deplementation approximation and the second	TIIX		a region and the second se	Charles (Charles) (Charles or Charles or Charles of Cha
Frequency Kc/s	Air gap + sample, cm	Withou trodin,	t elec-	With e	electro-		electro- by thick
		_ ∠3C	Q	C C	Q	C C	Q
	0.500	2.2	14	2.4	170	1.9	75
	0.400	4.9	13	4.9	340	4.1	97
EE	0.350	11.7	16	6.7	240	5.9	140
55	0.300	11.9	7	10.2	540	9.7	280
	0.275	16.4	6	13.5	570	12.4	320
	0.250	26.4	4	14.6	310	16.8	390
	0.225	37.1	1	27.4	300	25.6	270

When sample is touched: Without electroding K = 5.70 With electroding K = 4.14 With electroding by thicker paint K = 3.86

TABLE 36

Measurement of AC and Q of Unguarded Forsterite Sample with Varying Electrode Baking Time Using Capacitance Cell

#COMMON**********************************	Manifestation of Military repays (self) - Sec., report resource sections		baksa kali Manadaja - Pili mengan asada at pade enga 1999.	X	IV	erijana kanada on a samaniya kanada kanad	
Frequency Kc/s	Air gap + sample,cm		ctroded	With e ing 20 baking			electrod- 20 min.
		57.0	Q	<u> </u>		ΔC	
	0.500	1.7		1.2	96	1.9	150
	0.400	3.2	160	2.5	120	3.1	180
	0.300	6.2	84	5.2	82	5.8	330
55	0.250	9.4	65	7.9	68	8.2	380
	0.200	15.2	41	13.2	49	13.3	510
	0.175	22.7	30	19.1	36	18.3	700
	0.150	40.4	25	31.0	23	29.9	450
		Unmeasu able	r-	74.6	11	57.0	230

# When sample is touched:

With electroding, 20 min. baking K = 6.10 With electroding, 120 min. baking K = 4.61

TABLE 37

Measurement of Land Q of Lir Using Capacitance Cell

Frequency	Air Sap cm	Guard shiele ground	Guard and shielu both grounced	Sh St St	cec,	Guard ring having same potential and shield grounged	ng ame 1 and rounged	Upper electrote solderet, un- grancet, sideld grounced	octroae , un- slield	ungrounced and unshielced	უ უ ი
			The state of the s	7. T.	ੰ	K	)	X X	Budgerger at a de	Co. The second s	Bangin chambin
e - e monero de como de la composição de decom	0.500	6.27	16	7.09	25	6.58	56	6.04	52	1.29 178	.::
	0.200	4.87	17	5.33	24						
	0.100	5.55	24	3.47	32	5.65	40	2.79	25		
55 Zc/s	0.070	5.13	32	2.85	55						
	0.050	2.79	43	2.56	41						
	0.025	2.80	06	1.77	47	5.69	112	1.35	47	U.50 285	10
Call County space contains to the contains t	0.500	09.0	14	8.47	45	roman omercia de la deservación de la deservación de la defensación del la defensación del defensación de la defensación	No. of the control of				
100 Kc/s	0.200	5.19	16	5.70	45						
	0.100	3.71	25	5.67	5 0						
mengang kupadi ubuh dikumi kadi kadi kadi	E. G Mr. de . Mr. desidentenninn	er er sjugger adouenskibbioer o	A. Lee of the sheet of the co	Committee of the second	* **	under de des Meste Chroniton	TO 1-4 - Physical Processing - December - 19	Bridge and Mark Andrews	18、一種の 日本の一種 ・ 対象 ・ 本一 実の ・ 数	Miles and the second distribution of the second	First to althought.

. . Contc.

Table 57 (... Contc.)

	Alr Sall	Guarc and shield both grounded	and both ed	Unguaraea, shiela grouncea	haring same potential and shield erounded	soldered, un- guarded, shield grounded	ena un shield
		And the same of th	Ö	manufacture of the car		manufacturation and the first of the following manufacturation of the first of the fir	And the second s
	0.500	6.03	35	6.97 65	11.47 42	5.71 42	1.81 114
	0.200	4.81	4.1	5,29 75			
	0.100	5.50	58	3.44 76	3.54 65	2.7. 40	
l Fic/s	0.070			2.85 70			
	0.050	2.73	91	2.55 54			
	0.025	2,45	162	1.67 58	2.68 259	1.54 100	U.36 210
egy jeden er (film) – gall frækk kriste sykkelender – skik – sk	And Charles (1999) Ch	### - ### - ### #1 36-36 ## - '##1019## - #	AND - 20 - 20 - 40 - 4	the state care. The broken at the state at the state of t	radio A. Cura desage companye som conscient apo senso mos desages e designado en	() 10 · 10 · 10 · 10 · 10 · 10 · 10 · 10	en de describer de companyo en esta de com companyo en esta de companyo de companyo en esta de companyo en
	0.300	6.28	49				
	0.200	5.06	52				
lu Mc/s	0,100	5.76	89				
	0.050	5.03	85				

TABLE 38

Reasurement of AC and Q of Air Using Capacitance Cell

Air gap		Mc/s		[	55 Kc/s	
cm	A/t cm	∕,C	Q	A/t cm	<u> </u>	Ų
0.500	39 <b>.</b> 50	30.3	48	39.30	30.7	33
0.400	49.12	32.2	42	49.12	32.8	35
0.300	65.49	35.2	49	45.49	35.5	38
0.200	90.24	41.3	62	98.24	41.7	38
0.100	196.49	58.0	77	196.49	58.5	49
0.050	392.97	87.3	124	392.97	86.2	73
0.025	785.94	155.7	201	785.94	155.1	114

TABLE 39

Measurement of AC and Q of Air Using Capacitance Cell

Fro-				nguarded			earthed		
quenc	gap cm.	Arrang C	က် emen.r ⊤	Arrango C	emont 2	Arrang C	cement 1 Q	Arran, C	gement 2
	0.025	45.2	537	43.6	602	72.2	406	79.7	439
	0.100	14.8	202	15.3	254	27.5	169	29.0	164
70 <b>K</b> c/s	0.300	8.4	114	9.0	206	16.3	124	17.2	97
AC/S	0.500	7.8	109	8.0	114	13.3	122	14.9	87
			en maken saath rejaktivitadaan aach eeganteets			ha i na shini a comanda shini ka	nagyanya (Trop mananganana) daga sampuning <sup>angga</sup> daga sa		
	0.025	47.9	611	43.1	440	71.1	334	78.4	379
lMc/s	0.100	15.1	120	15.4	157	26.6	125	28.7	139
	0.300	8.5	73	9.4	109	16.9	191	17.0	87
	0.500	6.6	75	7.9	91	14.6	377	15.3	54

Arrangement 1 : Using pin connector

Arrangement 2: Pin connector was not used.

TABLE 40

Measurement of K and Q of Unelectroded and Unguarded Sample (AVII) Along with Air Using Capacitance Cell

ALONG THE RESIDENCE OF THE CONTRACT OF THE CON	Principal Comp. Compression of the Compression of t	the property of the property o	Shield early some and the second seco	
Frequency	Air gap + Sample cm	Arrangement 1		Arrangement 1 L
- Managaraha V. Samaraha - Samaraha Samaraha Manada	0.500	and the contract of the contra	- 1548	
	0,500		760	
55 Kc/s	0,20°		1187	
	0.111**		5.49 137	
and the state of the special control of the s	0,500	2402		678
	Ů.30Ű	801		2135
70 Kc/s	0,200	1		Ĭ
	0.111	3.8 488	5.84	727
go versido se esta una succidendo .	0.500	en mer riguages optimite utdeltide, i producet n. otto van . de / de van	The state of the	Manual Property of the Control of th
90 Kc/s	. 500 . 500		2305	
	0,111,**		6.65 654	9
est generales de la des desentes la les des		TO THE CONTROL OF THE PROPERTY	and the state of the companies of the second companies	Conta

Table 40 (... Conta.)

House, agent conduct, data serve at the revolve "beings" in other cells	un	Unshielded	Shield earthed		
Frequency	Air gap + sample cm	Arrangement 1 K	Arrangement 24 Arrangement 25	Arrangement 1 K 4	
and the second control of the second	0.500	· mail i completa di mandamentale del cel cel contra della del calcidada del calcid	1473	- 3138	
	0.500		- 6134	7713	
1 Mc/s	U.2000		3557		
	0.111		5.66 1007	5.99 1609	
A COURT - MANUAL CHILLIAN IN THE LANGE COMMANDE	0.500	3504	T220	在《唐····································	B-02
1,5 Mc/s	ಾನ್ ೦	974	4727		
	W.111 W	5.2 82u	6,52 1241		
grant the many of a state of the particular Common of	e particulari dessa de la celestra de la celestra de la composición de la composición de la composición de la celestra de la composición del composición de la composición de la composición del composición de la composición de la composición de la composición del composición de la composición de la composición del composición del composición del composición del composición del composición	the substitution of the su	enter de de la la verialmentation de provincia (menter destant destant destanta destanta destanta de la la la d	The care of the contract of th	

\*Sample was touched at this thickness by two electrodes, in other stages measurement was taken using hir and sample.

Arrangement 1: Fin connector was used

Arrangement 2A; Pin connector was not used.

Arrangement 25: Fin connector was not used and  $\Lambda {\tt C:C_1}$  was made higher than  $2L_*$ 

TABLE 41

Measurement of I sna ( of Forsterite Samples, Fired at 1200°C for 5 hours, in Capacitance Cell made of Aluminium

	I							
with	* 130 p. 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 . 150 .		disease in the case of the cas	Reministrate America		And the second second		White Committee
shield r cap d	r	354 353 186	91 84 90 15	534 513 262	272 238 263 62	258	253 270	276 254 232 148
Guarcea, micromete ungrounde	X	10.57 10.97 25.47	5.52 10.27 5.58 21.23	10.40 10.94 25.55	9.12 16.18 9.54 20.84	12.50	12.87 24.10	10.20 11.30 10.93
with	An other particular to							
shield er cap	J	336 296 130	88 113 100 24	505 453 215	240 164 232 86	urable C <sub>2</sub>	69	81 77 67 92
aea, omet naed		11.67 11.42 24.10	10.84 12.56 9.56 22.32	11.05 11.16 28.00	10.64 12.69 9.55 24.38	e Unmeasura	16.05 34.31	14.25 16.94 13.58 28.76
uard hiel roun		1.62 323 0.26 540 23.79 159	9.97 110 -2.52 131 -6.10 120 20.57 24	C.59 506 C.45 481 4.80 192	9.88 269 2.52 294 0.67 319 1.53 111		4.70 76 8.25 127	5.29 81 2.65 79 5.68 59 5.02 112
d, naeá		312 322 205 2	214 186 1 234 1 54 2	504 1 486 1 239 2	361 411 1453 152 2		260 1 241 2	293 314 1256 199 2
uarde hield ngrou	X	9.92 10.46 22.46	6.70 8.18 8.57 19.17	22.92 22.49 22.46	6.72 7.82 8.72 9.24	1.82	2.24	7.24 8.41 0.20 9.11
pample No.		104	L0104	H 0 7	-10104 -1	-	2 1 2 4 2	
Batch		63	td	G	19		65	B
Frequency			70 <u>10</u> /8	, ,	E 7. T. T.	AND THE CONTRACTOR AND THE CONTR	٠ د اوراد	

TABLE 42

Variation of the K Value with Change in Density

Batch No.	Density gms/cc	70 Kc/S	K l.1 Mc/S	ll Mc/S
WOOTE VE TERMINISTER TO SEE	2,05	4.1	4.2	4.2
c <sub>2</sub>	2.73	5.7	5.7	5.9
0	2.87	6.3	6.3	6.6
03	2.88	6.4	6.3	6.4
C	1.36	2.9	2.9	2.9
c <sub>4</sub>	1.98	3.7	3.7	3.8

TABLE 43

Weasurement of K and C of Electroded and Wired Forsterite Samples

age tanô x104	16	77		ω ,		ω	5	:- <del>1</del>
Average Q tar	616	1	2074		  - 	1228	707	)
2 0	924	583	1570	1657	1265	734	1122	503
25 Mc/s K Q	6.47	6.75	6.98	6.23	6.81	6,90 5.85	5.25	6.02
N ),	625	942	2419	1625	2410	1205	1176	265
10 Mc/S K	6.21	7.24	6.71	6.13	6.46	5.51	5.25	5.57
ري ري	809	1267	1285	1180	694	667 1304	1480	532
5 Mc/S K Q	6.20	98.9	6.07	6.02	6.81	5.80	5.30	5.57
S.	535	1929	3055	1215	1635	615	4.48	954
$\frac{1}{K}$ Mc/S	6.42	7.02	6.91	6.23	7.48	5.90	5.36	6.02
,c/s	615	1071	1355	682	1190	624	569	595
500 Kc/S K Q	6.21	6.48	6.37	5.82	6.91	5.80	5.36	5.80
Batch Sample 100 Kc/S No. No. K	388	3938	5477	1285	006	3424 752	208	394
	6.26	98.9	5.36	5.95	09.9	5.08	5.30	5.85
Sample No.	H	2	23	4	10	2	PM	PM2
Batch No.		G. Fure				Inte		

TABLE 44

Measurement of K of Electroded and Wired Forsterite Samples with Varying Thickness

Batch No.	Sample No.	100 Kc/S	500 Kc/S	K l Mc/s	5 Mc/S	10 Mc/S	25 Mc/S
	2A	6.86	6.48	7.02	6.86	7.24	6.75
C <sub>3</sub>	2B	6.29	6.41	6.25	6.18	6.22	6.37
	2C	6.23	6.30	6.20	6.18	6.19	6.28

Sample thickness: 2A - 0.5464 cm

2B - 0.3804 cm

2C - 0.2520 cm

Bowen and Schairer (1935)

Thilo and Rogge (1939)

Foster (1952)

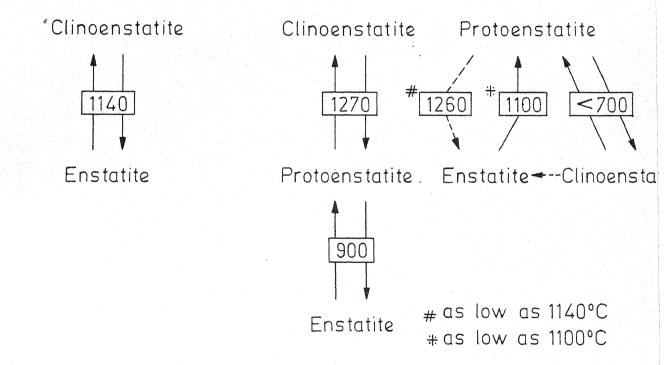


Fig. 1 Schemes of polymorphism of  $MgSiO_3$ . (Ref. 5)

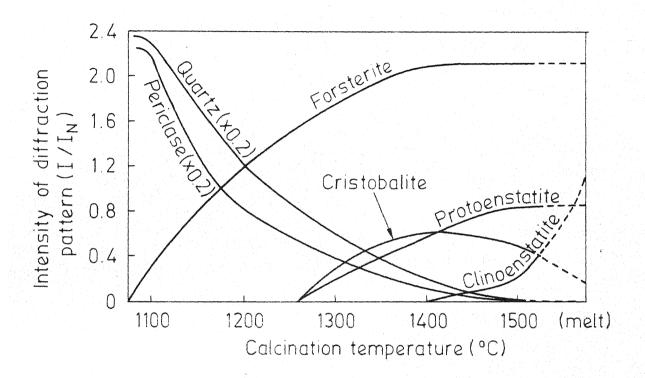


Fig 2 Intensity of diffraction patterns at various temperatures of calcination (Ref. 6, fig. 1)

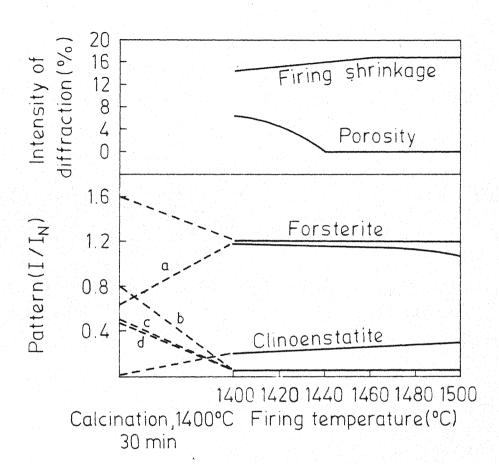


Fig. 3 Intensity changes of diffraction pattern of composition 95 % (2 MgO) (1.2 SiO<sub>2</sub>) with 5 % Kaolin (PSF - 0) [Ref. 6, fig 3].

(a) Protoenstatite (b) Cristobalite (c) Quartz (d) Periclase

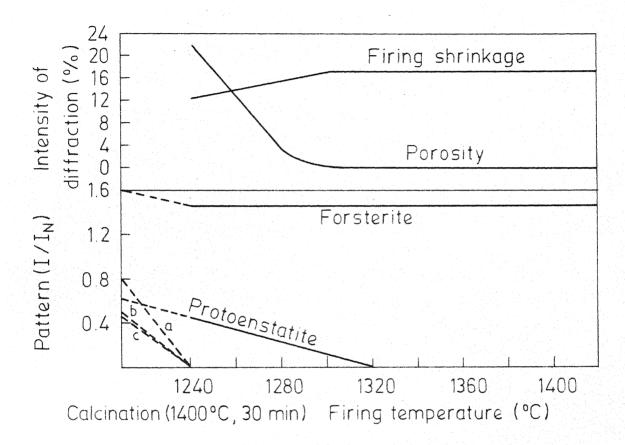
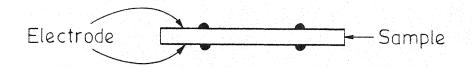
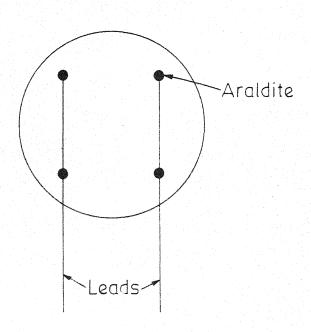


Fig. 4 Intensity changes of diffraction pattern of composition 85 % (2 MgO) (1.2 SiO $_2$ ) with 5 % Kaolin and 10 % BaCO $_3$  (PSF-B) [Ref 6, fig. 4].

(a) Cristobalite (b) Quartz (c) Periclase





Electroded and wired sample.

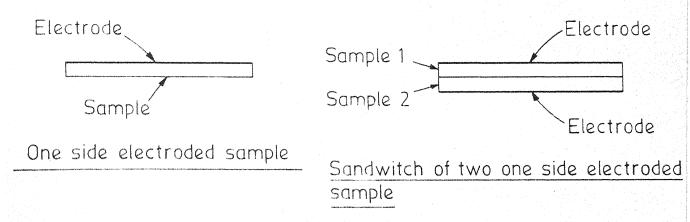


Fig. 6 Sketch of electroded and wired forsterite samples.

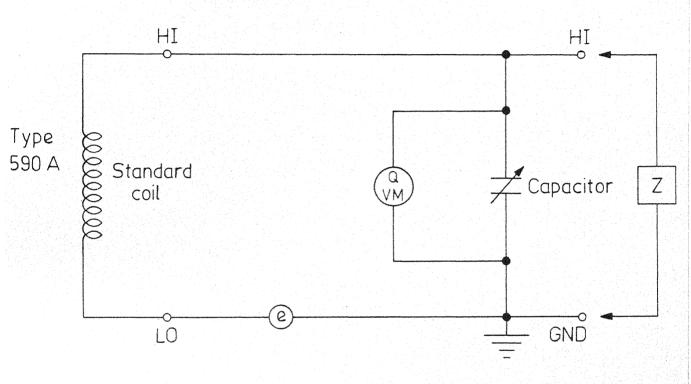
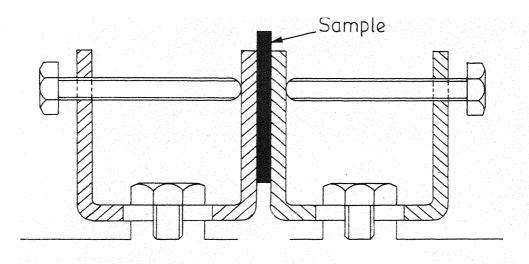
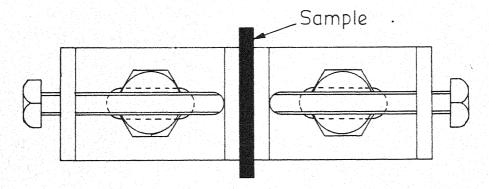


Fig. 7 Circuit for measuring the dielectric constant and Q-factor of the sintered disc samples by parallel connection.

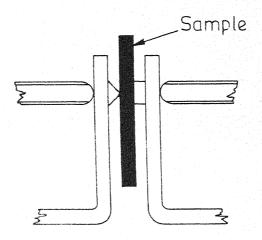
(details in appendix I)



# Elevation (arragement 1)



## Plan (arrangement 1)



Elevation (arrangement 2)

Fig. 8 Sketch of parallel plate setup for measuring K, the dielectric constant and Q, the quality factor of sintered forsterite sample.

5 0 45 0

Sketch of unavarded and unshielded capacitance cell for measuring K, the

Fia

9

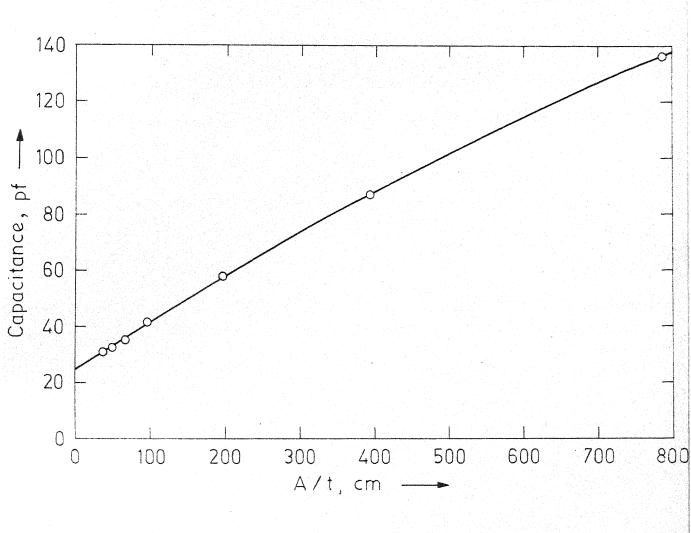


Fig. 11 C versus A/t plot for finding out actual K value of air.

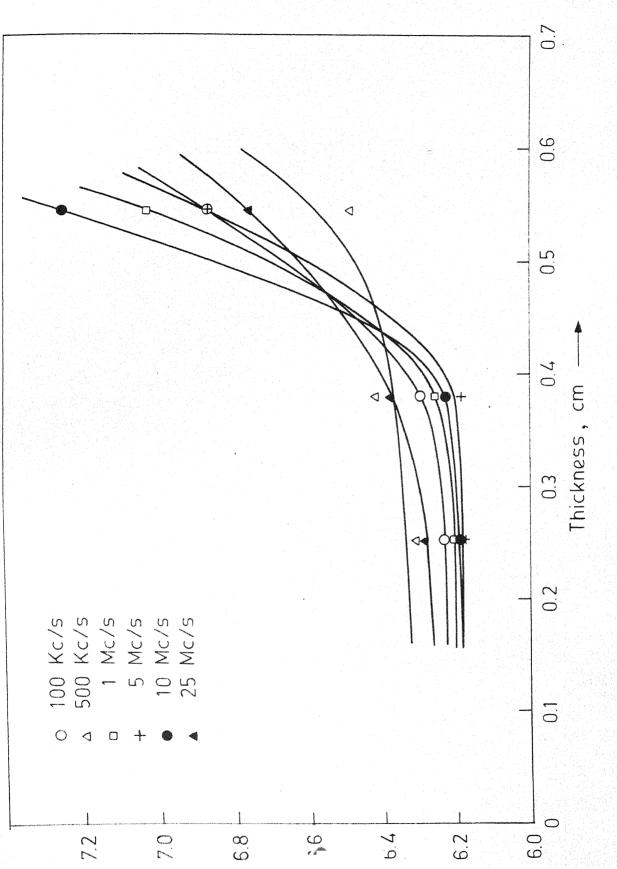


Fig. 12 Variation of relative dielectric constant K with sample thickness for a forsterite

#### REFERENCES

- 1. L. Navais, 'Advances in Ceramics Related to Electronic Tube Developments', Jr. Am. Cer. Soc. 37(8), 329-350 (1954).
- 2. L. Atlas, 'The Polymorphism of MgSiO<sub>3</sub> and Solid-State Equilibria in the System MgSiO<sub>3</sub>-CaMgSi<sub>2</sub>O<sub>6</sub>', Jr. Geology 6O(2), 125-47 (1952).
- 3. Hans Thurnauer, 'Low-loss Ceramic Lielectric', Tele. Tech., 6 (2), 86-87, 130 (1947).
- 4. V. D. Zaikina, 'Formation of Clinoenstatite in Synthetic Forsterite', (Met. Inst. Dneprepetrovsk) Ogneupouf 20(2), 79-82 (1955); Chem. Abstr. 50 (1956) 8153h.
- 5. W. R. Foster, 'High Temperature X-ray Diffraction Study of the Polymorphism of MgSiO<sub>3</sub>', Jr. Am. Cer. Soc. 34(9). 255-59 (1951).
- 6. M. Sugiura, M. Hirai, E. Ishii and S. Sano, 'Forsterite Porcelain as High Frequency Insulator, I: 'Properties of Forsterite Containing Excess Silica', Jr. Ceram. Assoc. Japan 67(10), 333-344 (1959).
- 7. R. Hayami and T. Ogura, 'Kinetics and Mechanism of Formation of Forsterite by Solid State Reaction of MgO and Enstatite', Jr. Ceram. Assoc. Japan 75(7), 215-220 (1967).
- 8. R. Hayami, 'Kinetics and Mechanisms of Formation of Enstatite by Solid State Reaction of Forsterite and SiO<sub>2</sub>; Jr. Ceram. Assoc. Japan 75(11), 343-347 (1967).
- 9. M. Sugiura, M. Hirai, S. Sano and E. Ishii, 'Forsterite Porcelain as a High Frequency Insulator, V: The Relation Between the Microstructure and the Electrical and Mechanical Properties of Forsterite Porcelain', Ir. Ceram. Assoc. Japan 70(6). 181-190 (1962).
- 10. S. Sano, E. Ishii, M. Hirai and M. Sugiura, 'The Forsterite Porcelain as a High Frequency Insulator, VII: Effect of kaolin Addition on Properties of Forsterite Porcelain', Jr. Ceram. Assoc. Japan 71(12),231-236 (1963).
- 11. A. Sugiara, S. Sano, E. Ishii and M. Hirai, 'Forsterite Porcelain as High Frequency Insulator, IV: The Relation Between the Microstructure and the Thermal Expansion of Forsterite Porcelain', Jr. Ceram. Assoc. Japan 70(4) 100-110 (1962).

- 12. E. Singer and Chr. Adolf, 'Forsterite Ceramics with the Same Thermal Expansion as Titanium', Ber. Leut. Keram. Ges. 37,3-6 (1960), Chem. Abstr. 54 (1960) 15880e.
- 13. Compagnie Generale de l'elegraphic, 'Ceramics for Low Dielectric Loss', Fans Fil Fr. 1,071,896, Sept. 6 (1954). Chem. Abstr. 55 (1959), 5623a.
- 14. General Electric Co. Brit. 'Forsterite Ceramic Bodies', 798, 450, July 25 (1958), Chem. Abstr. 53 (1959) 1665e.
- 15. N. Soga and O. L. Anderson, 'High Temperature Elasticity and Expansivity of Forsterite and Steatite', Jr. Am. Cer. Soc. 50(5) 239-42 (1967), Chem. Abstr. 67 (1967) 46718b.
- 16. E. Kanchin and V. Amburz, 'Thermal Dilatation of the Minerals in the System CaO-MgC-SiO<sub>2</sub>', Chem. Zvesti 19(1), 51-54(1965), Chem. Abstr. 62 (1965), 870le.
- 17. E. T. Smoke, 'Inorganic Dielectric Research', Rutgers State Univ. Coll. Res. Bull. 1970 No. 50,531 pp. Chem. Abstr. 72 (1970) 115646u.
- 18. P. G. Usov et al. (USSR) 'Tremolite, a Raw Material for High Frequency Ceramics', Sb. Tr. Molodykh Uch., Tomsk Polytech. Inst. 1973, No. 1, 87-90 (Russ), Chem. Abstr. (1974).
- 19. P. G. Usov et al. (USSR), 'Kinetics of Sintering of Forsterite Ceramics Produced from Magnesium Oxide Obtained by Various Methods', ibid. (1973), No. 1, 86-87 (Russ), Chem. Abstr.(1974).
- 20. P. G. Usov et al. (USSR), 'Preparation of Vacuum Compact High Frequency Lielectrics from Alguisk Talc', ibid. (1973), No. 1, 101103 (Huss), Chem. Abstr. (1974).
- 21. S. K. Gupta and A. R. Las, 'Effect of Processing Parameters on Microstructure Development and Magnetic Spectrum of Ni<sub>0.3</sub>Zn<sub>0.7</sub>Fe<sub>2</sub>O<sub>4</sub> Ferrite: II Magnetic Spectrum and its Correlation with Sintering Conditions and Microstructure', Tr. Ind. Cer. Soc. XXXVI (3), 55-60 (1977).
- 22. A. R. Das, 'Forsterite Ceramics for Low Loss Applications', Report No. CSIA-MT-(ARD)/77-79/29/I, December 1977, IIT Kanpur.
- 23. P. K. Ghosh and A. R. Das, 'Forsterite Ceramics for Low Loss Applications: Literature Review, X-ray Analysis, Sample Embrication and Investigation of Experimental Errors, Report No. CSIR-MT-(ARD)/77-79/29/II, October 1978.

- 24. A. R. von Hippel, Editor, 'Dielectric Materials and Applications', Technology Press, Cambriage, Massachusetts, John Wiley and Sons., New York, 1954.
- 25. L. Bragg and G. F. Claringbull, 'Crystal Structures of Minerals', Chap. IX p. 73, G. Bel, London (1965).
- 26. R. W. G. Wycoff, 'Crystal Structures', Vol. III, Chap.XII, aI 4, Interscience, New York.
- 27. W. D. Kingery, H. K. Bowen, D. R. Uhlmann, 'Introduction to Ceramics', Chap. 18, p. 947, John Wiley and Sons (1975).
- 28. 1967 Book of ASTM Standards, 'Electrical Insulating Materials', Part 29, p. 86, American Society for Testing and Materials.

### APPENDIX - I

Q-meter is an exceedingly useful instrument for measuring the characteristics of coils and capacitors at radio frequencies. The ratio between the voltage developed across the capacitive portion (C) of the resonant test circuit and the voltage injected into the circuit is actually measured.

 $Q = \frac{X}{R} = \frac{V_c}{e} \ , \ \text{where e is the voltage injected into the}$  test circuit and  $V_c$  is the voltage measured across the capacitor at resonance. e is maintained at 0.01 volt; therefore 100  $V_c$  will be equal to the circuit Q and the meter can be calibrated to read Q directly. This has been done in the 260-AP. In the equation above, X is the reactance of either the capacitor or the inductor, the values being equal at resonance; R is the sum of the resistances of the unknown and of the internal circuit, and the resultant Q reading is that of the circuit, rather than that of the unknown component alone. In most cases the Q of the unknown and the Q of the circuit differ by a negligible amount.

Derivation of the formulae used in Q-meter measurements are given below.

If the circuit is resonated at a value  $C_{\underline{l}}$  , with a Q-reading of  $G_{\underline{l}}$  before introducing the unknown, then

$$\frac{1}{\triangle C_1} = \triangle L \tag{1}$$

where L = Inductance

 $\omega = 2\pi f$ , where f = Frequency

 $C_1 = Capacitance$ 

and

$$Q_{1} = \frac{\Box I_{i}}{R} = \frac{1}{\Box C_{1}R}$$
 (2)

where R = Resistance.

The characteristics of an unknown connected in parallel are expressed most simply in terms of parallel  $X_p$  (Inductive or Capacitive reactance) and  $R_p$ . After the preliminary balance the addition of  $X_p$  requires a decrease in tuning capacitance (if X is capacitive) to a new value  $C_2$  and  $(C_2-C_1)$  is the effective parallel capacitance of the unknown. Now,

$$X_{p} = \frac{1}{\cos(C_2 - C_1)} \tag{3}$$

and

$$\frac{1}{R_{p}} = \frac{\omega c_{1}}{Q_{2}} - \frac{R}{R^{2} + \omega^{2}L^{2}}$$

$$= \frac{\omega c_{1}}{Q_{2}} - \frac{1}{R} \cdot \frac{1}{1 + \frac{\omega^{2}L^{2}}{R^{2}}}$$

$$= \frac{\omega c_{1}}{Q_{2}} - \frac{1}{RQ_{1}^{2}}$$

(Replacing 1 + 
$$Q_1^2$$
 by  $Q_1^2$ , since  $Q_1 >> 1$ ).

Using  $Q_1 = \frac{1}{\omega C_1 R}$ , we get  $R_p = \frac{Q_1 Q_2}{\omega C_1 (Q_1 - Q_2)}$  (4)

Therefore, 
$$Q_{\mathbf{X}} = \frac{\mathbb{R}_{\mathbf{p}}}{\mathbb{X}_{\mathbf{p}}} = \frac{\left(C_{2} - C_{1}\right) Q_{1}Q_{2}}{C_{1}\left(Q_{1} - Q_{2}\right)}$$
 (5)

#### APPENDIX - II

A dielectric material reacts to an electric field differently from a free space because it contains charge carriers that can be displaced, and charge displacements within the dielectric can neutralise a part of the applied field. Since, V = Q/C, where V is the applied voltage and Q is the electrical charge that can be stored, and  $C = K'C_O$ , where K' is relative dielectric constant and  $C_O$  is the capacitance in vacuum, we can write for a capacitor containing a dielectric

$$V = \frac{Q/K'}{C_O} \tag{1}$$

That is, only a fraction of the total charge, the free charge Q/K', sets up an electric field and voltage toward outside; the remainder, the bound charge, is neutralised by polarization of the dielectric. The total electric flux density D can be represented as the sum of the electric field E and dipole charge P:

$$D = \varepsilon_0 E + P = \varepsilon' E$$
 (2)

where the polarization is the surface charge density of the bound charge, equal to dipole moment per unit volume of material. In the above equation,  $\epsilon_0$  and  $\epsilon'$  are the dielectric permittivity of vacuum and the dielectric material respectively.

In an ideal capacitor the electric charge adjusts itself instantaneously to any change in voltage. In practice, however, there is an inertia to charge movement that shows up as a relaxation time for charge transport and we have a dependence of dielectric constant on frequency. If the applied electric field is alternating at sufficiently low frequencies the polarization will also alternate. increasing frequency, the polarization will eventually have difficulty in following the field and will not have time to attain its full value before the field reverses. increasing frequency in this range the relative permittivity decreases (the 'dispersion' of the relative permittivity) and there is also a loss, or absorption, of electrical energy which causes heating in the dielectric. The electronic polarization is the only process sufficiently rapid to follow alternative fields in the visible part of the spectrum. Ionic polarization processes are able to follow an applied high frequency field and contribute to the dielectric constant at frequencies up to the infrared region of the spectrum. Orientation and space polarization have relaxation times corresponding to the particular system and process but, in general, participate only at lower frequencies.

In discussing the properties of a dislectric, it is convenient to imagine the material situated between the electrodes of a capacitor. However, similar considerations

apply wherever the material appears in an electric field, e.g. as insulation on wires forming connecting leads or coils, or in the electric field associated with electromagnetic wave propagation.

Considering a perfect loss free capacitor (e.g. two plane parallel plates in a vacuum) of capacitance C, having an applied alternating electric potential defined by the equation:

$$E = E_0 \cos \omega t \tag{3}$$

where E is the potential at time t,  $E_0$  is the maximum value of the potential,  $\omega$  is the frequency in radians per second, and t is the time.

The displacement current vector is 90 degrees out of phase with the potential. Thus, there is zero component of the current in phase with the potential and no electrical energy is lost by conversion to heat.

If a dielectric is placed in the capacitor the displacement current vector will be slightly less ( $\delta$ ) than 90 degrees ahead of potential. Representing the electric field and displacement (flux density) in complex notation:

$$\mathbb{E} = \mathbb{E}_{o} e^{i \cdot c \cdot v t}$$
 (4)

$$D = D_0 e^{i(\omega t - \delta)}$$
 (5)

and making use of the relation

$$D = K^{*} E$$
 (6)

one obtains

$$K^{*} = K_{S} e^{-i\delta} = K_{S} (6 \circ s\delta - i \sin \delta)$$
 (7)

where  $K_s = \nu_o/E_o$  is the static dielectric constant. In terms of a complex dielectric constant,

$$\mathbb{K}^{\mathbb{X}} = \mathbb{K}' - i\mathbb{K}'' = \frac{\varepsilon^{\mathbb{X}}}{\varepsilon_{0}} = \frac{1}{\varepsilon_{0}} (\varepsilon' - i\varepsilon'')$$
 (8)

one has from Eq. 7

$$K' = K_S \cos \delta$$
 (9)

$$K^{r} = K_S \sin \delta$$
 (10)

and from Eqs. 9 and 10 the loss tangent is given by,

$$tan \delta = K''/K' = \epsilon''/\epsilon'$$
 (11)

This phase shift corresponding to a time lag between an applied voltage and induced current causes loss currents and energy dissipation in ac circuits which do not require charge carrier migration.

The maximum dielectric loss occurs when the period of the relaxation process, whatever it may be, is the same as the period of the applied field. When the relaxation time is large compared with the period of the applied field, losses are small. Similarly when the relaxation process is rapid compared with the frequency of the applied field, losses are small.

The frequency dependence of the relative permittivity  $\epsilon'$  and dielectric loss factor  $\epsilon''$  for relaxation absorption are

described by the 'Debye' equations.

$$\varepsilon' = \varepsilon'_{\alpha} + \frac{\varepsilon'_{0} - \varepsilon'_{\alpha}}{1 + (\cdot)^{2} \tau^{2}}$$
 (12)

$$\varepsilon'' = (\varepsilon_0' - \varepsilon_\alpha') \frac{\omega \tau}{1 + \omega^2 \tau^2}$$
 (13)

$$\therefore \tan \delta = \frac{\varepsilon''}{\varepsilon'} = \frac{(\varepsilon'_0 - \varepsilon'_{\alpha}) \omega \tau}{\varepsilon'_0 + \varepsilon'_{\alpha} \omega^2 \tau^2}$$
 (14)

where  $\epsilon_0'$  and  $\epsilon_{\alpha}'$  are the relative permittivities below and above the absorption respectively; the factor  $\epsilon_0' - \epsilon_{\alpha}'$  being termed the dissipation of the relative permittivity; is the frequency in radians per second; and  $\tau$  is the relaxation time of the system, which characterizes the rate of build up or decay of the polarization when an electric field is suddenly applied or removed.

The above equations apply to both liquids and solids although different models are used in their derivation.

The Debye equations are based on the assumption that the transient polarization can be represented by a simple exponential with a single relaxation time. Hence any model which predicts a simple exponential rise of polarization on applying a field will, in an ac field, lead to dielectric dispersion and absorption curves of the form given by eqns. 12, 13 and 14. For most materials, however, the values experimental/are not well described by the Debye equations.

Energy losses in dielectrics result from three primary processes:

- 1. Ion migration losses
  - (a) Dc conductivity losses
  - (b) Ion jump and cipole relaxation losses
- 2. Ion vibration and deformation losses.
- 3. Electron polarization losses.

Of these electron polarization losses give rise to absorption and colour in the visible spectrum. Ion vibration and deformation losses become important in the infrared but are not a major concern for frequencies below about 10<sup>10</sup> Hz. By far the major factor affecting the use of ceramic materials is the ion migration losses which tend to increase at low frequencies and as the temperature is raised.

The loss factor can be written in terms of the electrical conductivity,

$$\omega \epsilon^{\mu} = \sigma = \omega \epsilon^{\prime} \tan \delta$$
 (15)

or 
$$\tan \delta = \frac{\sigma}{2\pi f K' \epsilon_0} = \frac{\sigma}{(8.85 \text{kl}0^{-14})(2\pi f)K'}$$
 (16)

where conductivity is given in ohm-cm<sup>-1</sup>. These conduction migration losses are normally small.

The total value for tanó is the sum of individual contributions already discussed. At lower frequencies conduction losses become important, at moderate frequencies ion jump and dipole losses are most important, at intermediate frequencies dielectric losses are small, and at sufficiently high frequencies ion polarization effects give energy absorption.

For reasonably good insulators the conductivity increases exponentially with temperature. Consequently, for this process we would expect  $\tan\delta$  to increase exponentially with temperature, as indicated in Eq. 16.

### BIBLIOGRAPHY

- 1. W. D. Kingery, H. K. Bowen, D. R. Uhlmann, 'Introduction to Ceramics', Chap. 18, John Wiley and Sons, 1975.
- 2. J. B. Birks and J. Hart, editors, 'Progress in Dielectrics', p 151, Heywood and Company Ltd., 1961.
- 3. H. Frohilich, 'Theory of Dielectrics', Oxford University Press, 1958.
- 4. C. P. Smyth, 'Dielectric Behaviour and Structure', McGraw-Hill Book Company, 1955.
- 5. C. J. F. Bottcher, 'Theory of Electric Polarisation', Elsevier Publishing Company, 1952.